

# LPC2210/2220

# 16/32-bit ARM microcontrollers; flashless, with 10-bit ADC and external memory interface

Rev. 06 — 11 December 2008

**Product data sheet** 

# 1. General description

The LPC2210/2220 microcontrollers are based on a 16/32-bit ARM7TDMI-S CPU with real-time emulation and embedded trace support. For critical code size applications, the alternative 16-bit Thumb mode reduces code by more than 30 % with minimal performance penalty.

With their 144-pin package, low power consumption, various 32-bit timers, 8-channel 10-bit ADC, PWM channels, and up to nine external interrupt pins these microcontrollers are particularly suitable for industrial control, medical systems, access control and point-of-sale. The LPC2210/2220 can provide up to 76 GPIOs depending on bus configuration. With a wide range of serial communications interfaces, it is also very well suited for communication gateways, protocol converters and embedded soft modems as well as many other general-purpose applications.

**Remark:** Throughout the data sheet, the term LPC2210/2220 will apply to devices with and without the /01 suffix. The /01 suffix will be used to differentiate LPC2210 devices only when necessary.

### 2. Features

# 2.1 Key features

- 16/32-bit ARM7TDMI-S microcontroller in a LQFP144 and TFBGA144 package.
- 16/64 kB on-chip static RAM (LPC2210/2220).
- Serial bootloader using UART0 provides in-system download and programming capabilities.
- EmbeddedICE-RT and Embedded Trace interfaces offer real-time debugging with the on-chip RealMonitor software as well as high-speed real-time tracing of instruction execution.
- **■** Eight channel 10-bit ADC with conversion time as low as 2.44 μs.
  - LPC2210/01 and LPC2220 only: Dedicated result registers for ADC(s) reduce interrupt overhead. The ADC pads are 5 V tolerant when configured for digital I/O function(s).
- Two 32-bit timers (LPC2220 and LPC2210/01 also external event counters) with four capture and four compare channels, PWM unit (six outputs), Real-Time Clock (RTC), and watchdog.
- Multiple serial interfaces including two UARTs (16C550), Fast I<sup>2</sup>C-bus (400 kbit/s) and two SPIs.
  - ◆ LPC2210/01 and LPC2220 only: A Synchronous Serial Port (SSP) with data buffers and variable length transfers can be selected to replace one SPI.



- LPC2210/01 and LPC2220 only: UART0/1 include fractional baud rate generator, auto-bauding capabilities, and handshake flow-control fully implemented in hardware.
- Vectored Interrupt Controller (VIC) with configurable priorities and vector addresses.
- Configurable external memory interface with up to four banks, each up to 16 MB and 8/16/32-bit data width.
- Up to 76 general purpose pins (5 V tolerant) capable. Up to nine edge/level sensitive external interrupt pins available.
  - ◆ LPC2210/01 and LPC2220 only: Fast GPIO ports enable port pin toggling up to 3.5 times faster than the original device. They also allow for a port pin to be read at any time regardless of its function.
- 60 MHz (LPC2210) and 75 MHz (LPC2210/01 and LPC2220) maximum CPU clock available from programmable on-chip Phase-Locked Loop (PLL) with settling time of 100 μs.
- On-chip integrated oscillator operates with external crystal in range of 1 MHz to 25 MHz and with external oscillator up to 25 MHz.
- Power saving modes include Idle and Power-down.
- Processor wake-up from Power-down mode via external interrupt.
- Individual enable/disable of peripheral functions for power optimization.
- Dual power supply:
  - CPU operating voltage range of 1.65 V to 1.95 V (1.8 V  $\pm$  0.15 V).
  - I/O power supply range of 3.0 V to 3.6 V (3.3 V  $\pm$  10 %) with 5 V tolerant I/O pads. 16/32-bit ARM7TDMI-S processor.

#### **Ordering information** 3.

Table 1. **Ordering information** 

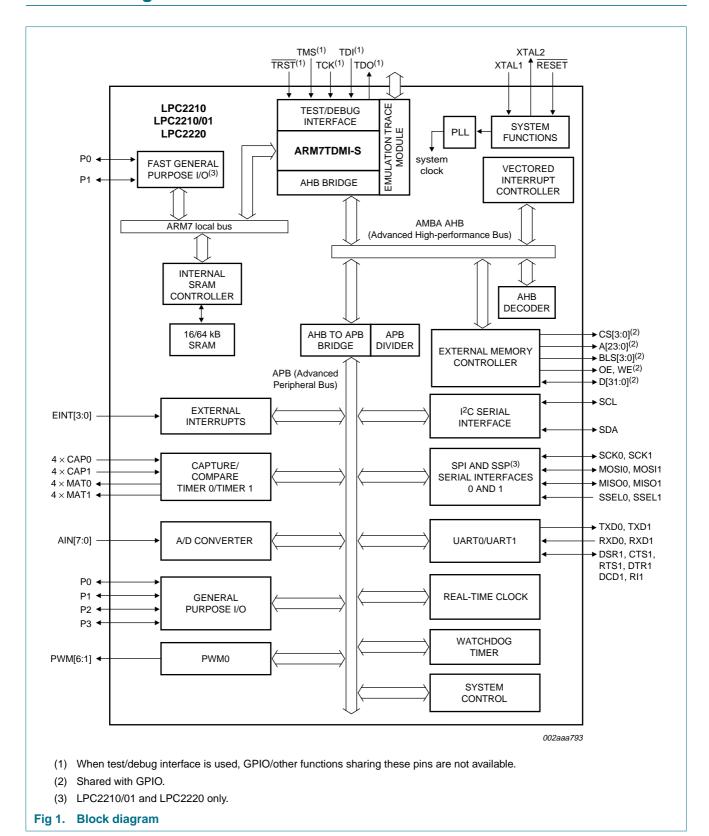
Type number	Package								
	Name	Description	Version						
LPC2210FBD144	LQFP144	plastic low profile quad flat package; 144 leads; body $20 \times 20 \times 1.4$ mm	SOT486-1						
LPC2210FBD144/01	LQFP144	plastic low profile quad flat package; 144 leads; body $20 \times 20 \times 1.4$ mm	SOT486-1						
LPC2220FBD144	LQFP144	plastic low profile quad flat package; 144 leads; body $20 \times 20 \times 1.4$ mm	SOT486-1						
LPC2220FET144	TFBGA144	plastic thin fine-pitch ball grid array package; 144 balls; body $12 \times 12 \times 0.8$ mm	SOT569-2						
LPC2220FET144/G	TFBGA144	plastic thin fine-pitch ball grid array package; 144 balls; body $12 \times 12 \times 0.8$ mm	SOT569-2						

# 3.1 Ordering options

Table 2. Ordering options

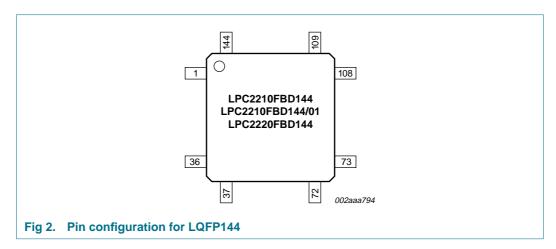
Type number	RAM	Fast GPIO/ SSP/ Enhanced UART, ADC, Timer	Temperature range
LPC2210FBD144	16 kB	no	–40 °C to +85 °C
LPC2210FBD144/01	16 kB	yes	–40 °C to +85 °C
LPC2220FBD144	64 kB	yes	–40 °C to +85 °C
LPC2220FET144	64 kB	yes	–40 °C to +85 °C
LPC2220FET144/G	64 kB	yes	–40 °C to +85 °C

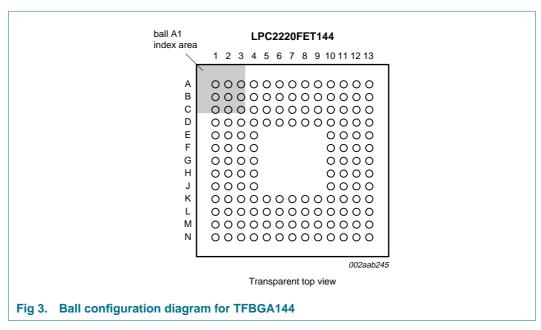
# 4. Block diagram



# 5. Pinning information

# 5.1 Pinning





Row	Column													
	1	2	3	4	5	6	7	8	9	10	11	12	13	
Α	P2.22/ D22	V <sub>DDA(1V8)</sub>	P1.28/ TDI	P2.21/ D21	P2.18/ D18	P2.14/ D14	P1.29/ TCK	P2.11/ D11	P2.10/ D10	P2.7/D7	$V_{DD(3V3)}$	V <sub>DD(1V8)</sub>	P2.4/	
В	V <sub>DD(3V3)</sub>	P1.27/ TDO	XTAL2	V <sub>SSA(PLL)</sub>	P2.19/ D19	P2.15/ D15	P2.12/ D12	P0.20/ MAT1.3/ SSEL1/ EINT3	V <sub>DD(3V3)</sub>	P2.6/D6	V <sub>SS</sub>	P2.3/D3	$V_{SS}$	
С	P0.21/ PWM5/ CAP1.3	V <sub>SS</sub>	XTAL1	V <sub>SSA</sub>	RESET	P2.16/ D16	P2.13/ D13	P0.19/ MAT1.2/ MOSI1/ CAP1.2	P2.9/D9	P2.5/D5	P2.2/D2	P2.1/D1	V <sub>DD(</sub>	
D	P0.24	P1.19/ TRACEP KT3	P0.23	P0.22/ CAP0.0/ MAT0.0	P2.20/ D20	P2.17/ D17	V <sub>SS</sub>	P0.18/ CAP1.3/ MISO1/ MAT1.3	P2.8/D8	P1.30/ TMS	V <sub>SS</sub>	P1.20/ TRACES YNC	P0.1 CAP SCK MAT	
Е	P2.25/ D25	P2.24/ D24	P2.23/ D23	V <sub>SS</sub>						P0.16/ EINT0/ MAT0.2/ CAP0.2	P0.15/ RI1/ EINT2	P2.0/D0	P3.3 BLS	
F	P2.27/ D27/ BOOT1	P1.18/ TRACEP KT2	V <sub>DDA(3V3)</sub>	P2.26/ D26/ BOOT0						P3.31/ BLS0	P1.21/ PIPESTAT 0	V <sub>DD(3V3)</sub>	$V_{SS}$	
G	P2.29/ D29	P2.28/ D28	P2.30/ D30/AIN4	P2.31/ D31/AIN5							P0.14/ DCD1/ EINT1	P1.0/CS0	P3.0/A0	P1.1
Н	P0.25	n.c.	P0.27/ AIN0/ CAP0.1/ MAT0.1	P1.17/ TRACEP KT1						D	P0.13/ DTR1/ MAT1.1	P1.22/ PIPESTAT 1	P3.2/A2	P3.1/
J	P0.28/ AIN1/ CAP0.2/ MAT0.2	$V_{SS}$	P3.29/ BLS2/ AIN6	P3.28/ BLS3/ AIN7						P3.3/A3	P1.23/ PIPESTAT 2	P0.11/ CTS1/ CAP1.1	P0.12 DSR MAT	
K	P3.27/WE	P3.26/ CS1	V <sub>DD(3V3)</sub>	P3.22/ A22	P3.20/ A20	P0.1/ RXD0/ PWM3/ EINT0	P3.14/ A14	P1.25/ EXTIN0	P3.11/ A11	V <sub>DD(3V3)</sub>	P0.10/ RTS1/ CAP1.0	V <sub>SS</sub>	P3.4/	

Tab Rov	e 3. Ball	allocation .	continued										
Rov	v Column												
2220 6	1	2	3	4	5	6	7	8	9	10	11	12	13
L	P0.29/ AIN2/ CAP0.3/ MAT0.3	P0.30/ AIN3/ EINT3/ CAP0.0	P1.16/ TRACEP KT0	P0.0/ TXD0/ PWM1	P3.19/ A19	P0.2/ SCL/ CAP0.0	P3.15/ A15	P0.4/ SCK0/ CAP0.1	P3.12/ A12	V <sub>SS</sub>	P1.24/ TRACEC LK	P0.8/ TXD1/ PWM4	P0.9/ RXD1/ PWM6/ EINT3
M	P3.25/ CS2	P3.24/ CS3	V <sub>DD(3V3)</sub>	P1.31/ TRST	P3.18/ A18	V <sub>DD(3V3)</sub>	P3.16/ A16	P0.3/ SDA/ MAT0.0/ EINT1	P3.13/ A13	P3.9/A9	P0.7/ SSEL0/ PWM2/ EINT2	P3.7/A7	P3.5/A5
N	V <sub>DD(1V8)</sub>	$V_{SS}$	P3.23/ A23/ XCLK	P3.21/ A21	P3.17/ A17	P1.26/ RTCK	$V_{SS}$	V <sub>DD(3V3)</sub>	P0.5/ MISO0/ MAT0.1	P3.10/ A10	P0.6/ MOSI0/ CAP0.2	P3.8/A8	P3.6/A6

# 5.2 Pin description

Table 4. Pin description

P0.0 to P0.31  P0.0/TXD0/ PWM1	42[1]		I/O	<b>Port 0:</b> Port 0 is a 32-bit bidirectional I/O port with individual direction controls for each bit. The operation of port 0 pins	
	42 <sup>[1]</sup>				depends upon the pin function selected via the Pin Connect Block.
	42 <mark>[1]</mark>			Pins 26 and 31 of port 0 are not available.	
		L4[1]	0	<b>TXD0</b> — Transmitter output for UART0.	
F VVIVI I			0	<b>PWM1</b> — Pulse Width Modulator output 1.	
P0.1/RXD0/	49 <u>[2]</u>	K6 <sup>[2]</sup>	I	<b>RXD0</b> — Receiver input for UART0.	
PWM3/EINT0			0	<b>PWM3</b> — Pulse Width Modulator output 3.	
			l	EINT0 — External interrupt 0 input	
P0.2/SCL/ CAP0.0	50[ <u>3]</u>	L6[3]	I/O	<b>SCL</b> — I <sup>2</sup> C-bus clock input/output. Open-drain output (for I <sup>2</sup> C-bus compliance).	
			I	<b>CAP0.0</b> — Capture input for Timer 0, channel 0.	
P0.3/SDA/ 5 MAT0.0/EINT1	58 <sup>[3]</sup>	M8[3]	I/O	<b>SDA</b> — I <sup>2</sup> C-bus data input/output. Open-drain output (for I <sup>2</sup> C-bus compliance).	
			0	MAT0.0 — Match output for Timer 0, channel 0.	
			I	EINT1 — External interrupt 1 input.	
CAP0.1	59 <u>[1]</u>	D[1] L8[1]	I/O	<b>SCK0</b> — Serial clock for SPI0. SPI clock output from master or input to slave.	
			I	CAP0.1 — Capture input for Timer 0, channel 1.	
P0.5/MISO0/ 61 MAT0.1	61 <mark>1</mark> 1	N9[1]	I/O	<b>MISO0</b> — Master In Slave OUT for SPI0. Data input to SPI master or data output from SPI slave.	
			0	MAT0.1 — Match output for Timer 0, channel 1.	
P0.6/MOSI0/ CAP0.2	68 <u>[1]</u>	[1] N11 <sup>[1]</sup>	I/O	<b>MOSI0</b> — Master Out Slave In for SPI0. Data output from SPI master or data input to SPI slave.	
			I	CAP0.2 — Capture input for Timer 0, channel 2.	
P0.7/SSEL0/ PWM2/EINT2	69 <sup>[2]</sup>	M11 <sup>[2]</sup>	I	<b>SSEL0</b> — Slave Select for SPI0. Selects the SPI interface as a slave.	
			0	PWM2 — Pulse Width Modulator output 2.	
			I	EINT2 — External interrupt 2 input.	
P0.8/TXD1/	75 <u>[1]</u>	L12[1]	0	TXD1 — Transmitter output for UART1.	
PWM4			0	PWM4 — Pulse Width Modulator output 4.	
P0.9/RXD1/	76 <u>[2]</u>	L13[2]	I	RXD1 — Receiver input for UART1.	
PWM6/EINT3			0	PWM6 — Pulse Width Modulator output 6.	
			I	EINT3 — External interrupt 3 input.	
P0.10/RTS1/	78 <u>[1]</u>	K11[1]	0	RTS1 — Request to Send output for UART1.	
CAP1.0			I	CAP1.0 — Capture input for Timer 1, channel 0.	
P0.11/CTS1/	83 <u>[1]</u>	J12[1]	I	CTS1 — Clear to Send input for UART1.	
CAP1.1			I	CAP1.1 — Capture input for Timer 1, channel 1.	
P0.12/DSR1/ MAT1.0	84 <u>[1]</u>	J13 <mark>11</mark>	I	<b>DSR1</b> — Data Set Ready input for UART1.	
			0	MAT1.0 — Match output for Timer 1, channel 0.	

 Table 4.
 Pin description ...continued

Symbol	Pin (LQFP)	Pin (TFBGA)	Туре	Description
P0.13/DTR1/	85 <u>[1]</u>	H10[1]	0	<b>DTR1</b> — Data Terminal Ready output for UART1.
MAT1.1			0	MAT1.1 — Match output for Timer 1, channel 1.
P0.14/DCD1/	92[2]	G10 <sup>[2]</sup>	I	<b>DCD1</b> — Data Carrier Detect input for UART1.
EINT1			I	EINT1 — External interrupt 1 input.
				Note: LOW on this pin while RESET is LOW forces on-chip bootloader to take over control of the part after reset.
P0.15/RI1/	99[2]	E11[2]	I	RI1 — Ring Indicator input for UART1.
EINT2			1	EINT2 — External interrupt 2 input.
P0.16/EINT0/	100[2]	E10 <sup>[2]</sup>	I	EINT0 — External interrupt 0 input.
MAT0.2/CAP0.2			0	MAT0.2 — Match output for Timer 0, channel 2.
			I	CAP0.2 — Capture input for Timer 0, channel 2.
P0.17/CAP1.2/	101111	D13[1]	I	CAP1.2 — Capture input for Timer 1, channel 2.
SCK1/MAT1.2			I/O	SCK1 — Serial Clock for SPI1/SSI/Microwire. SPI/SSI/Microwire clock output from master or input to slave.
			0	MAT1.2 — Match output for Timer 1, channel 2.
P0.18/CAP1.3/	121[1]	D8[1]	I	CAP1.3 — Capture input for Timer 1, channel 3.
MISO1/MAT1.3			I/O	<b>MISO1</b> — Master In Slave Out for SPI1. Data input to SPI master or data output from SPI slave.
			0	MAT1.3 — Match output for Timer 1, channel 3.
P0.19/MAT1.2/ MOSI1/CAP1.2	122[1]		0	MAT1.2 — Match output for Timer 1, channel 2.
			I/O	<b>MOSI1</b> — Master Out Slave In for SPI1. Data output from SP master or data input to SPI slave.
				SPI interface: MOSI line.
				<ul> <li>SSI: DX/RX line (SPI1 as a master/slave).</li> </ul>
				<ul> <li>Microwire: SO/SI line (SPI1 as a master/slave).</li> </ul>
			l	CAP1.2 — Capture input for Timer 1, channel 2.
P0.20/MAT1.3/	123[2]	B8[2]	0	<b>MAT1.3</b> — Match output for Timer 1, channel 3.
SSEL1/ EINT3			I	<b>SSEL1</b> — Slave Select for SPI1/Microwire. Used to select the SPI or Microwire interface as a slave. Frame synchronization in case of 4-wire SSI.
			I	EINT3 — External interrupt 3 input.
P0.21/PWM5/	4 <u>[1]</u>	C1[1]	0	<b>PWM5</b> — Pulse Width Modulator output 5.
CAP1.3			I	CAP1.3 — Capture input for Timer 1, channel 3.
P0.22/CAP0.0/	5 <u>[1]</u>	D4[1]	I	<b>CAP0.0</b> — Capture input for Timer 0, channel 0.
MAT0.0			0	MAT0.0 — Match output for Timer 0, channel 0.
P0.23	6 <u>[1]</u>	D3[1]	I/O	General purpose bidirectional digital port only.
P0.24	8 <u>[1]</u>	D1[1]	I/O	General purpose bidirectional digital port only.
P0.25	21[1]	H1[1]	I/O	General purpose bidirectional digital port only.
P0.27/AIN0/ CAP0.1/MAT0.1	23[4]	H3[4]	I	<b>AINO</b> — ADC, input 0. This analog input is always connected to its pin.
			I	CAP0.1 — Capture input for Timer 0, channel 1.
			0	MAT0.1 — Match output for Timer 0, channel 1.

 Table 4.
 Pin description ...continued

Symbol	Pin (LQFP)	Pin (TFBGA)	Туре	Description
P0.28/AIN1/ CAP0.2/MAT0.2	25 <mark>[4]</mark>	J1 <sup>[4]</sup>	1	<b>AIN1</b> — ADC, input 1. This analog input is always connected to its pin.
			I	CAP0.2 — Capture input for Timer 0, channel 2.
			0	MAT0.2 — Match output for Timer 0, channel 2.
P0.29/AIN2/ CAP0.3/MAT0.3	32[4]	L1 <sup>[4]</sup>	I	<b>AIN2</b> — ADC, input 2. This analog input is always connected to its pin.
			I	CAP0.3 — Capture input for Timer 0, Channel 3.
			0	MAT0.3 — Match output for Timer 0, channel 3.
P0.30/AIN3/ EINT3/CAP0.0	33[4]	L2 <sup>[4]</sup>	I	<b>AIN3</b> — ADC, input 3. This analog input is always connected to its pin.
			I	EINT3 — External interrupt 3 input.
			I	<b>CAP0.0</b> — Capture input for Timer 0, channel 0.
P1.0 to P1.31			I/O	<b>Port 1:</b> Port 1 is a 32-bit bidirectional I/O port with individual direction controls for each bit. The operation of port 1 pins depends upon the pin function selected via the Pin Connect Block.
	(e)	rei		Pins 0 through 15 of port 1 are not available.
P1.0/CS0	91 <u><sup>5</sup></u>	G11 <u>5</u>	0	CS0 — LOW-active Chip Select 0 signal.
D4.4/ <del>OF</del>	0.0[5]	040[5]	0	(Bank 0 addresses range 0x8000 0000 to 0x80FF FFFF)
P1.1/OE	90[5]	G13 <sup>[5]</sup>	0	OE — LOW-active Output Enable signal.
P1.16/ TRACEPKT0	34 <u>[5]</u>	L3[5]	0	<b>TRACEPKT0</b> — Trace Packet, bit 0. Standard I/O port with internal pull-up.
P1.17/ TRACEPKT1	24[5]	H4[5]	0	<b>TRACEPKT1</b> — Trace Packet, bit 1. Standard I/O port with internal pull-up.
P1.18/ TRACEPKT2	15 <sup>[5]</sup>	F2 <sup>[5]</sup>	0	<b>TRACEPKT2</b> — Trace Packet, bit 2. Standard I/O port with internal pull-up.
P1.19/ TRACEPKT3	7 <u>[5]</u>	D2[5]	0	<b>TRACEPKT3</b> — Trace Packet, bit 3. Standard I/O port with internal pull-up.
P1.20/ TRACESYNC	102[5]	D12[5]	0	TRACESYNC — Trace Synchronization. Standard I/O port with internal pull-up.  Note: LOW on this pin while RESET is LOW, enables pins P1[25:16] to operate as Trace port after reset.
P1.21/ PIPESTAT0	95 <u>[5]</u>	F11 <sup>[5]</sup>	0	PIPESTAT0 — Pipeline Status, bit 0. Standard I/O port with internal pull-up.
P1.22/ PIPESTAT1	86 <sup>[5]</sup>	H11 <sup>[5]</sup>	0	PIPESTAT1 — Pipeline Status, bit 1. Standard I/O port with internal pull-up.
P1.23/ PIPESTAT2	82[5]	J11 <u><sup>5</sup></u>	0	<b>PIPESTAT2</b> — Pipeline Status, bit 2. Standard I/O port with internal pull-up.
P1.24/ TRACECLK	70 <u><sup>[5]</sup></u>	L11 <sup>5</sup>	0	<b>TRACECLK</b> — Trace Clock. Standard I/O port with internal pull-up.
P1.25/EXTIN0	60 <u><sup>[5]</sup></u>	K8[5]	I	<b>EXTIN0</b> — External Trigger Input. Standard I/O with internal pull-up.

 Table 4.
 Pin description ...continued

the JTAG port. Assists debugger synchronization we processor frequency varies. Bidirectional pin with in pull-up.  Note: LOW on this pin while RESET is LOW, enable P1[31:26] to operate as Debug port after reset.  P1.27/TDO 144 <sup>[5]</sup> B2 <sup>[5]</sup> O TDO — Test Data out for JTAG interface.  P1.28/TDI 140 <sup>[5]</sup> A3 <sup>[5]</sup> I TDI — Test Data in for JTAG interface.  P1.29/TCK 126 <sup>[5]</sup> A7 <sup>[5]</sup> I TCK — Test Clock for JTAG interface. This clock me slower than 1/6 of the CPU clock (CCLK) for the JTAG to operate.  P1.30/TMS 113 <sup>[5]</sup> D10 <sup>[5]</sup> I TMS — Test Mode Select for JTAG interface.  P1.31/TRST 43 <sup>[5]</sup> M4 <sup>[5]</sup> I TRST — Test Reset for JTAG interface.  P2.0 to P2.31  VO Port 2 — Port 2 is a 32-bit bidirectional I/O port with direction controls for each bit. The operation of port	Symbol	Pin (LQFP)	Pin (TFBGA)	Туре	Description
P1_27/TDO 144  B2  B2  O TDO — Test Data out for JTAG interface.  P1_28/TDI 140  B2  A3  I TDI — Test Data out for JTAG interface.  P1_29/TCK 126  A7  ID	P1.26/RTCK	52 <sup>[5]</sup>	N6 <sup>[5]</sup>	I/O	
P1.28/TDI					Note: LOW on this pin while RESET is LOW, enables pins P1[31:26] to operate as Debug port after reset.
P1.29/TCK	P1.27/TDO	144 <mark>5</mark>	B2[5]	0	TDO — Test Data out for JTAG interface.
Slower than ½ of the CPU clock (CCLK) for the JTAI to operate.	P1.28/TDI	140 <mark>5</mark>	A3[5]	I	TDI — Test Data in for JTAG interface.
P1.31/TRST 43 5  M4 5  I TRST — Test Reset for JTAG interface.  P2.0 to P2.31    VO   Port 2 — Port 2 is a 32-bit bidirectional I/O port with direction controls for each bit. The operation of port depends upon the pin function selected via the Pin Block.  P2.0/D0 98 5  E12 5  I/O D0 — External memory data line 0.  P2.1/D1 105 6  C12 6  I/O D1 — External memory data line 1.  P2.2/D2 106 6  C11 6  I/O D2 — External memory data line 2.  P2.3/D3 108 5  B12 5  I/O D3 — External memory data line 3.  P2.4/D4 109 6  A13 6  I/O D4 — External memory data line 3.  P2.5/D5 114 6  C10 5  I/O D5 — External memory data line 5.  P2.6/D6 115 6  B10 5  I/O D5 — External memory data line 6.  P2.7/D7 116 6  A10 5  I/O D6 — External memory data line 6.  P2.7/D7 116 6  A10 5  I/O D7 — External memory data line 7.  P2.8/D8 117 6  D9 6  I/O D7 — External memory data line 7.  P2.8/D8 117 6  D9 6  I/O D9 — External memory data line 9.  P2.10/D10 120 5  A9 6  I/O D10 — External memory data line 10.  P2.11/D11 124 6  A8 6  I/O D11 — External memory data line 10.  P2.11/D11 124 6  A8 6  I/O D12 — External memory data line 11.  P2.12/D12 125 6  B7 6  I/O D12 — External memory data line 12.  P2.13/D13 127 6  C7 6  I/O D13 — External memory data line 14.  P2.15/D15 130 6  B6 6  I/O D14 — External memory data line 15.  P2.16/D16 131 6  C6 6  I/O D15 — External memory data line 15.  P2.16/D16 131 6  C6 6  I/O D16 — External memory data line 16.  P2.17/D17 132 6  D6 6  I/O D15 — External memory data line 17.  P2.18/D18 133 6  A5 6  I/O D16 — External memory data line 18.  P2.19/D19 134 6  B5 6  I/O D16 — External memory data line 19.  P2.20/D20 136 6  D5 6  I/O D17 — External memory data line 20.  P2.21/D21 137 6  A4 6  I/O D20 — External memory data line 21.  P2.22/D22 15 1 A1 6  I/O D20 — External memory data line 22.  P2.23/D23 10 6  E3 6  I/O D30 — External memory data line 23.	P1.29/TCK	126 <sup>[5]</sup>	A7[5]	I	<b>TCK</b> — Test Clock for JTAG interface. This clock must be slower than $\frac{1}{6}$ of the CPU clock (CCLK) for the JTAG interface to operate.
P2.0 to P2.31    VO	P1.30/TMS	113 <u><sup>[5]</sup></u>	D10 <sup>[5]</sup>	I	TMS — Test Mode Select for JTAG interface.
December   December	P1.31/TRST	43 <u>[5]</u>	M4[5]	I	TRST — Test Reset for JTAG interface.
P2.1/D1 1055 C125 I/O D1 — External memory data line 1. P2.2/D2 1065 C115 I/O D2 — External memory data line 2. P2.3/D3 1085 B126 I/O D3 — External memory data line 3. P2.4/D4 1095 A135 I/O D4 — External memory data line 4. P2.5/D5 1145 C105 I/O D5 — External memory data line 6. P2.6/D6 1155 B105 I/O D6 — External memory data line 6. P2.7/D7 1165 A105 I/O D7 — External memory data line 7. P2.8/D8 1175 D95 I/O D8 — External memory data line 8. P2.9/D9 1185 C35 I/O D9 — External memory data line 9. P2.10/D10 1205 A365 I/O D10 — External memory data line 10. P2.11/D11 1245 A865 I/O D11 — External memory data line 11. P2.12/D12 1255 B715 I/O D12 — External memory data line 12. P2.13/D13 1275 C715 I/O D13 — External memory data line 13. P2.14/D14 1295 A665 I/O D14 — External memory data line 14. P2.15/D15 1305 B665 I/O D15 — External memory data line 15. P2.16/D16 1315 C665 I/O D16 — External memory data line 16. P2.17/D17 1325 D665 I/O D16 — External memory data line 17. P2.18/D18 1335 A565 I/O D17 — External memory data line 18. P2.19/D19 1345 B555 I/O D18 — External memory data line 18. P2.19/D19 1345 B556 I/O D18 — External memory data line 19. P2.20/D20 1365 D565 I/O D19 — External memory data line 19. P2.21/D21 1375 A465 I/O D19 — External memory data line 20. P2.21/D21 1375 A465 I/O D20 — External memory data line 21. P2.22/D22 150 A150 I/O D22 — External memory data line 22. P2.23/D23 1055 E350 I/O D22 — External memory data line 23.	P2.0 to P2.31			I/O	<b>Port 2</b> — Port 2 is a 32-bit bidirectional I/O port with individual direction controls for each bit. The operation of port 2 pins depends upon the pin function selected via the Pin Connect Block.
P2.2/D2         1065         C115         I/O         D2 — External memory data line 2.           P2.3/D3         1085         B126         I/O         D3 — External memory data line 3.           P2.4/D4         1095         A136         I/O         D4 — External memory data line 4.           P2.5/D5         1145         C105         I/O         D5 — External memory data line 5.           P2.6/D6         1155         B105         I/O         D6 — External memory data line 6.           P2.7/D7         1165         A105         I/O         D7 — External memory data line 7.           P2.8/D8         1175         D96         I/O         D8 — External memory data line 7.           P2.9/D9         1185         C96         I/O         D9 — External memory data line 8.           P2.9/D9         1185         C96         I/O         D10 — External memory data line 9.           P2.10/D10         1205         A96         I/O         D10 — External memory data line 10.           P2.11/D11         1245         A86         I/O         D11 — External memory data line 11.           P2.12/D12         1255         B76         I/O         D13 — External memory data line 13.           P2.14/D14         1295         A66         I/O         D14 —	P2.0/D0	98 <mark>[5]</mark>	E12[5]	I/O	<b>D0</b> — External memory data line 0.
P2.3/D3 108 <sup>[5]</sup> B12 <sup>[5]</sup> I/O D3 — External memory data line 3.  P2.4/D4 109 <sup>[5]</sup> A13 <sup>[5]</sup> I/O D4 — External memory data line 4.  P2.5/D5 114 <sup>[5]</sup> C10 <sup>[5]</sup> I/O D5 — External memory data line 5.  P2.6/D6 115 <sup>[5]</sup> B10 <sup>[5]</sup> I/O D6 — External memory data line 6.  P2.7/D7 116 <sup>[5]</sup> A10 <sup>[5]</sup> I/O D7 — External memory data line 7.  P2.8/D8 117 <sup>[5]</sup> D9 <sup>[5]</sup> I/O D8 — External memory data line 8.  P2.9/D9 118 <sup>[5]</sup> C9 <sup>[5]</sup> I/O D9 — External memory data line 9.  P2.10/D10 120 <sup>[5]</sup> A9 <sup>[5]</sup> I/O D10 — External memory data line 10.  P2.11/D11 124 <sup>[5]</sup> A8 <sup>[5]</sup> I/O D11 — External memory data line 11.  P2.12/D12 125 <sup>[5]</sup> B7 <sup>[5]</sup> I/O D12 — External memory data line 12.  P2.13/D13 127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O D13 — External memory data line 13.  P2.14/D14 129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O D14 — External memory data line 14.  P2.15/D15 130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O D15 — External memory data line 15.  P2.16/D16 131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O D16 — External memory data line 16.  P2.17/D17 132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O D17 — External memory data line 17.  P2.18/D18 133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O D18 — External memory data line 18.  P2.19/D19 134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O D19 — External memory data line 19.  P2.20/D20 136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O D19 — External memory data line 20.  P2.21/D21 137 <sup>[5]</sup> A4 <sup>[6]</sup> I/O D20 — External memory data line 21.  P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O D22 — External memory data line 22.  P2.23/D23 10 <sup>[6]</sup> E3 <sup>[6]</sup> I/O D22 — External memory data line 23.	P2.1/D1	105 <mark>5</mark>	C12 <sup>[5]</sup>	I/O	D1 — External memory data line 1.
P2.4/D4         109 <sup>[5]</sup> A13 <sup>[5]</sup> I/O         D4 — External memory data line 4.           P2.5/D5         114 <sup>[5]</sup> C10 <sup>[5]</sup> I/O         D5 — External memory data line 5.           P2.6/D6         115 <sup>[5]</sup> B10 <sup>[5]</sup> I/O         D6 — External memory data line 6.           P2.7/D7         116 <sup>[5]</sup> A10 <sup>[5]</sup> I/O         D7 — External memory data line 7.           P2.8/D8         117 <sup>[5]</sup> D9 <sup>[5]</sup> I/O         D8 — External memory data line 8.           P2.9/D9         118 <sup>[5]</sup> C9 <sup>[5]</sup> I/O         D9 — External memory data line 9.           P2.10/D10         120 <sup>[5]</sup> A9 <sup>[5]</sup> I/O         D10 — External memory data line 10.           P2.11/D11         124 <sup>[5]</sup> A8 <sup>[5]</sup> I/O         D11 — External memory data line 11.           P2.12/D12         125 <sup>[5]</sup> B7 <sup>[5]</sup> I/O         D12 — External memory data line 12.           P2.13/D13         127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O         D13 — External memory data line 14.           P2.14/D14         129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O         D14 — External memory data line 15.           P2.16/D16         131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O         D16 — External memory data line 17.	P2.2/D2	106 <u><sup>[5]</sup></u>	C11 <sup>[5]</sup>	I/O	<b>D2</b> — External memory data line 2.
P2.5/D5         114[5]         C10[5]         I/O         D5 — External memory data line 5.           P2.6/D6         115[5]         B10[5]         I/O         D6 — External memory data line 6.           P2.7/D7         116[5]         A10[5]         I/O         D7 — External memory data line 7.           P2.8/D8         117[5]         D9[5]         I/O         D8 — External memory data line 8.           P2.9/D9         118[5]         C9[5]         I/O         D9 — External memory data line 9.           P2.10/D10         120[5]         A9[5]         I/O         D10 — External memory data line 10.           P2.11/D11         124[5]         A8[5]         I/O         D11 — External memory data line 11.           P2.12/D12         125[5]         B7[5]         I/O         D12 — External memory data line 12.           P2.13/D13         127[6]         C7[5]         I/O         D13 — External memory data line 13.           P2.14/D14         129[5]         A6[5]         I/O         D14 — External memory data line 14.           P2.15/D15         130[5]         B6[5]         I/O         D15 — External memory data line 16.           P2.16/D16         131[5]         C6[5]         I/O         D16 — External memory data line 17.           P2.18/D18         133[5] <td>P2.3/D3</td> <td>108<u><sup>[5]</sup></u></td> <td>B12[5]</td> <td>I/O</td> <td>D3 — External memory data line 3.</td>	P2.3/D3	108 <u><sup>[5]</sup></u>	B12[5]	I/O	D3 — External memory data line 3.
P2.6/D6 115 B10 B10 I/O D6 — External memory data line 6. P2.7/D7 116 A10 I/O D7 — External memory data line 7. P2.8/D8 117 D9 D9 I/O D8 — External memory data line 8. P2.9/D9 118 C9 I/O D9 — External memory data line 9. P2.10/D10 120 A9 I/O D10 — External memory data line 10. P2.11/D11 124 A8 I/O D11 — External memory data line 11. P2.12/D12 125 B7 I/O D12 — External memory data line 12. P2.13/D13 127 C7 I/O D13 — External memory data line 13. P2.14/D14 129 A6 I/O D14 — External memory data line 14. P2.15/D15 130 B6 I/O D15 — External memory data line 15. P2.16/D16 131 C6 I/O D16 — External memory data line 16. P2.17/D17 132 D6 I/O D16 — External memory data line 17. P2.18/D18 133 A5 I/O D17 — External memory data line 18. P2.19/D19 134 I/O D18 — External memory data line 19. P2.20/D20 136 D5 I/O D19 — External memory data line 20. P2.21/D21 137 A4 I/O D20 — External memory data line 21. P2.22/D22 15 A15 I/O D22 — External memory data line 22. P2.23/D23 106 E3 I/O D23 — External memory data line 22. P2.23/D23 106 E35 I/O D22 — External memory data line 23.	P2.4/D4	109 <u>[5]</u>	A13 <sup>[5]</sup>	I/O	<b>D4</b> — External memory data line 4.
P2.7/D7       116       A10       I/O       D7 — External memory data line 7.         P2.8/D8       117       D9       I/O       D8 — External memory data line 8.         P2.9/D9       118       C9       I/O       D9 — External memory data line 9.         P2.10/D10       120       A9       I/O       D10 — External memory data line 10.         P2.11/D11       124       A8       I/O       D11 — External memory data line 11.         P2.12/D12       125       B7       I/O       D12 — External memory data line 12.         P2.13/D13       127       C7       I/O       D13 — External memory data line 13.         P2.14/D14       129       A6       I/O       D14 — External memory data line 14.         P2.15/D15       130       B6       I/O       D15 — External memory data line 15.         P2.16/D16       131       C6       I/O       D16 — External memory data line 16.         P2.17/D17       132       D6       I/O       D17 — External memory data line 17.         P2.18/D18       133       A5       I/O       D18 — External memory data line 18.         P2.19/D19       134       B5       I/O       D19 — External memory data line 20.         P2.21/D21       137       A4       I	P2.5/D5	114 <u><sup>[5]</sup></u>	C10 <sup>[5]</sup>	I/O	<b>D5</b> — External memory data line 5.
P2.8/D8       117 <sup>[5]</sup> D9 <sup>[5]</sup> I/O       D8 — External memory data line 8.         P2.9/D9       118 <sup>[5]</sup> C9 <sup>[5]</sup> I/O       D9 — External memory data line 9.         P2.10/D10       120 <sup>[5]</sup> A9 <sup>[5]</sup> I/O       D10 — External memory data line 10.         P2.11/D11       124 <sup>[5]</sup> A8 <sup>[5]</sup> I/O       D11 — External memory data line 11.         P2.12/D12       125 <sup>[5]</sup> B7 <sup>[5]</sup> I/O       D13 — External memory data line 12.         P2.13/D13       127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O       D14 — External memory data line 13.         P2.14/D14       129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O       D15 — External memory data line 14.         P2.15/D15       130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O       D16 — External memory data line 15.         P2.16/D16       131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O       D16 — External memory data line 16.         P2.17/D17       132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O       D17 — External memory data line 17.         P2.18/D18       133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O       D18 — External memory data line 19.         P2.20/D20       136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O       D20 — External memory data line 20.         P2.21/D21       137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O	P2.6/D6	115 <u><sup>[5]</sup></u>	B10 <sup>[5]</sup>	I/O	<b>D6</b> — External memory data line 6.
P2.9/D9         118 <sup>[5]</sup> C9 <sup>[5]</sup> I/O         D9 — External memory data line 9.           P2.10/D10         120 <sup>[5]</sup> A9 <sup>[5]</sup> I/O         D10 — External memory data line 10.           P2.11/D11         124 <sup>[5]</sup> A8 <sup>[5]</sup> I/O         D11 — External memory data line 11.           P2.12/D12         125 <sup>[5]</sup> B7 <sup>[5]</sup> I/O         D12 — External memory data line 12.           P2.13/D13         127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O         D13 — External memory data line 13.           P2.14/D14         129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O         D14 — External memory data line 14.           P2.15/D15         130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O         D15 — External memory data line 15.           P2.16/D16         131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O         D16 — External memory data line 16.           P2.17/D17         132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O         D17 — External memory data line 17.           P2.18/D18         133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O         D18 — External memory data line 18.           P2.19/D19         134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O         D19 — External memory data line 20.           P2.20/D20         136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O         D21 — External memory data line 21. </td <td>P2.7/D7</td> <td>116<sup>[5]</sup></td> <td>A10<sup>[5]</sup></td> <td>I/O</td> <td><b>D7</b> — External memory data line 7.</td>	P2.7/D7	116 <sup>[5]</sup>	A10 <sup>[5]</sup>	I/O	<b>D7</b> — External memory data line 7.
P2.10/D10       120[5]       A9[5]       I/O       D10 — External memory data line 10.         P2.11/D11       124[5]       A8[5]       I/O       D11 — External memory data line 11.         P2.12/D12       125[5]       B7[5]       I/O       D12 — External memory data line 12.         P2.13/D13       127[5]       C7[5]       I/O       D13 — External memory data line 13.         P2.14/D14       129[5]       A6[5]       I/O       D14 — External memory data line 14.         P2.15/D15       130[5]       B6[5]       I/O       D15 — External memory data line 15.         P2.16/D16       131[5]       C6[5]       I/O       D16 — External memory data line 16.         P2.17/D17       132[5]       D6[5]       I/O       D17 — External memory data line 17.         P2.18/D18       133[5]       A5[5]       I/O       D18 — External memory data line 18.         P2.19/D19       134[5]       B5[5]       I/O       D19 — External memory data line 20.         P2.20/D20       136[5]       D5[5]       I/O       D20 — External memory data line 21.         P2.21/D21       137[5]       A4[5]       I/O       D21 — External memory data line 22.         P2.22/D22       1[6]       A1[5]       I/O       D22 — External memory data line 23.     <	P2.8/D8	117 <u>5</u>	D9[5]	I/O	<b>D8</b> — External memory data line 8.
P2.11/D11 124 <sup>[5]</sup> A8 <sup>[5]</sup> I/O D11 — External memory data line 11. P2.12/D12 125 <sup>[5]</sup> B7 <sup>[5]</sup> I/O D12 — External memory data line 12. P2.13/D13 127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O D13 — External memory data line 13. P2.14/D14 129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O D14 — External memory data line 14. P2.15/D15 130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O D15 — External memory data line 15. P2.16/D16 131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O D16 — External memory data line 16. P2.17/D17 132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O D17 — External memory data line 17. P2.18/D18 133 <sup>[5]</sup> A5 <sup>[6]</sup> I/O D18 — External memory data line 18. P2.19/D19 134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O D19 — External memory data line 19. P2.20/D20 136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O D20 — External memory data line 20. P2.21/D21 137 <sup>[5]</sup> A4 <sup>[6]</sup> I/O D21 — External memory data line 21. P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O D22 — External memory data line 22. P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O D23 — External memory data line 23.	P2.9/D9	118 <mark>5</mark>	C9[5]	I/O	<b>D9</b> — External memory data line 9.
P2.12/D12 125 B7 I/O D12 — External memory data line 12. P2.13/D13 127 C7 I/O D13 — External memory data line 13. P2.14/D14 129 A6 I/O D14 — External memory data line 14. P2.15/D15 130 B6 I/O D15 — External memory data line 15. P2.16/D16 131 C6 I/O D16 — External memory data line 16. P2.17/D17 132 D6 I/O D17 — External memory data line 17. P2.18/D18 133 A5 I/O D18 — External memory data line 18. P2.19/D19 134 B5 I/O D19 — External memory data line 19. P2.20/D20 136 D5 I/O D20 — External memory data line 20. P2.21/D21 137 A45 I/O D21 — External memory data line 21. P2.22/D22 15 A15 I/O D22 — External memory data line 22. P2.23/D23 105 E35 I/O D23 — External memory data line 23.	P2.10/D10	120 <u><sup>[5]</sup></u>	A9[5]	I/O	<b>D10</b> — External memory data line 10.
P2.13/D13 127 <sup>[5]</sup> C7 <sup>[5]</sup> I/O D13 — External memory data line 13.  P2.14/D14 129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O D14 — External memory data line 14.  P2.15/D15 130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O D15 — External memory data line 15.  P2.16/D16 131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O D16 — External memory data line 16.  P2.17/D17 132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O D17 — External memory data line 17.  P2.18/D18 133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O D18 — External memory data line 18.  P2.19/D19 134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O D19 — External memory data line 19.  P2.20/D20 136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O D20 — External memory data line 20.  P2.21/D21 137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O D21 — External memory data line 21.  P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O D22 — External memory data line 22.  P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O D23 — External memory data line 23.	P2.11/D11	124 <u><sup>5</sup></u>	A8[5]	I/O	<b>D11</b> — External memory data line 11.
P2.14/D14 129 <sup>[5]</sup> A6 <sup>[5]</sup> I/O D14 — External memory data line 14.  P2.15/D15 130 <sup>[5]</sup> B6 <sup>[5]</sup> I/O D15 — External memory data line 15.  P2.16/D16 131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O D16 — External memory data line 16.  P2.17/D17 132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O D17 — External memory data line 17.  P2.18/D18 133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O D18 — External memory data line 18.  P2.19/D19 134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O D19 — External memory data line 19.  P2.20/D20 136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O D20 — External memory data line 20.  P2.21/D21 137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O D21 — External memory data line 21.  P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O D22 — External memory data line 22.  P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O D23 — External memory data line 23.	P2.12/D12	125 <sup>[5]</sup>	B7[5]	I/O	<b>D12</b> — External memory data line 12.
P2.15/D15	P2.13/D13	127 <u><sup>5</sup></u>	C7 <sup>[5]</sup>	I/O	<b>D13</b> — External memory data line 13.
P2.16/D16 131 <sup>[5]</sup> C6 <sup>[5]</sup> I/O D16 — External memory data line 16. P2.17/D17 132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O D17 — External memory data line 17. P2.18/D18 133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O D18 — External memory data line 18. P2.19/D19 134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O D19 — External memory data line 19. P2.20/D20 136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O D20 — External memory data line 20. P2.21/D21 137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O D21 — External memory data line 21. P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O D22 — External memory data line 22. P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O D23 — External memory data line 23.	P2.14/D14	129 <u><sup>[5]</sup></u>	A6 <sup>[5]</sup>	I/O	<b>D14</b> — External memory data line 14.
P2.17/D17       132 <sup>[5]</sup> D6 <sup>[5]</sup> I/O       D17 — External memory data line 17.         P2.18/D18       133 <sup>[5]</sup> A5 <sup>[5]</sup> I/O       D18 — External memory data line 18.         P2.19/D19       134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O       D19 — External memory data line 19.         P2.20/D20       136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O       D20 — External memory data line 20.         P2.21/D21       137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O       D21 — External memory data line 21.         P2.22/D22       1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O       D22 — External memory data line 22.         P2.23/D23       10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O       D23 — External memory data line 23.	P2.15/D15	130 <u><sup>[5]</sup></u>	B6 <sup>[5]</sup>	I/O	<b>D15</b> — External memory data line 15.
P2.18/D18       133[5]       A5[5]       I/O       D18 — External memory data line 18.         P2.19/D19       134[5]       B5[5]       I/O       D19 — External memory data line 19.         P2.20/D20       136[5]       D5[5]       I/O       D20 — External memory data line 20.         P2.21/D21       137[5]       A4[5]       I/O       D21 — External memory data line 21.         P2.22/D22       1[5]       A1[5]       I/O       D22 — External memory data line 22.         P2.23/D23       10[5]       E3[5]       I/O       D23 — External memory data line 23.	P2.16/D16	131 <u><sup>5</sup></u>	C6[5]	I/O	<b>D16</b> — External memory data line 16.
P2.19/D19       134 <sup>[5]</sup> B5 <sup>[5]</sup> I/O       D19 — External memory data line 19.         P2.20/D20       136 <sup>[5]</sup> D5 <sup>[5]</sup> I/O       D20 — External memory data line 20.         P2.21/D21       137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O       D21 — External memory data line 21.         P2.22/D22       1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O       D22 — External memory data line 22.         P2.23/D23       10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O       D23 — External memory data line 23.	P2.17/D17	132 <u><sup>[5]</sup></u>	D6 <sup>[5]</sup>	I/O	<b>D17</b> — External memory data line 17.
P2.20/D20       136[5]       D5[5]       I/O       D20 — External memory data line 20.         P2.21/D21       137[5]       A4[5]       I/O       D21 — External memory data line 21.         P2.22/D22       1[5]       A1[5]       I/O       D22 — External memory data line 22.         P2.23/D23       10[5]       E3[5]       I/O       D23 — External memory data line 23.	P2.18/D18	133 <u><sup>[5]</sup></u>	A5 <sup>[5]</sup>	I/O	<b>D18</b> — External memory data line 18.
P2.21/D21       137 <sup>[5]</sup> A4 <sup>[5]</sup> I/O       D21 — External memory data line 21.         P2.22/D22       1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O       D22 — External memory data line 22.         P2.23/D23       10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O       D23 — External memory data line 23.	P2.19/D19	134 <u><sup>[5]</sup></u>	B5 <sup>[5]</sup>	I/O	<b>D19</b> — External memory data line 19.
P2.22/D22 1 <sup>[5]</sup> A1 <sup>[5]</sup> I/O <b>D22</b> — External memory data line 22. P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O <b>D23</b> — External memory data line 23.	P2.20/D20	136 <sup>[5]</sup>	D5[5]	I/O	<b>D20</b> — External memory data line 20.
P2.23/D23 10 <sup>[5]</sup> E3 <sup>[5]</sup> I/O <b>D23</b> — External memory data line 23.	P2.21/D21	137 <u><sup>5</sup></u>	A4[5]	I/O	<b>D21</b> — External memory data line 21.
·	P2.22/D22	1 <sup>[5]</sup>	A1 <sup>[5]</sup>	I/O	D22 — External memory data line 22.
P2.24/D24 11 <sup>5</sup> E2 <sup>5</sup> I/O <b>D24</b> — External memory data line 24.	P2.23/D23	10[5]	E3[5]	I/O	<b>D23</b> — External memory data line 23.
	P2.24/D24	11 <u>5</u>	E2[5]	I/O	<b>D24</b> — External memory data line 24.
P2.25/D25 12 <sup>[5]</sup> E1 <sup>[5]</sup> I/O <b>D25</b> — External memory data line 25.	P2.25/D25	12 <sup>[5]</sup>	E1[5]	I/O	D25 — External memory data line 25.

 Table 4.
 Pin description ...continued

Symbol	Pin (LQFP)	Pin (TFBGA)		Description	
P2.26/D26/	13 <sup>[5]</sup>	F4[5]	I/O	<b>D26</b> — External memory data line 26.	
BOOT0			I	<b>BOOT0</b> — While RESET is LOW, together with BOOT1 controls booting and internal operation. Internal pull-up ensures HIGH state if pin is left unconnected.	
P2.27/D27/	16 <sup>[5]</sup>	F1 <sup>[5]</sup>	I/O	<b>D27</b> — External memory data line 27.	
BOOT1			I	<b>BOOT1</b> — While RESET is LOW, together with BOOT0 controls booting and internal operation. Internal pull-up ensures HIGH state if pin is left unconnected.	
				BOOT1:0 = 00 selects 8-bit memory on $\overline{CS0}$ for boot.	
				BOOT1:0 = 01 selects 16-bit memory on $\overline{CS0}$ for boot.	
				BOOT1:0 = 10 selects 32-bit memory on $\overline{CS0}$ for boot.	
				BOOT1:0 = 11 selects 16-bit memory on $\overline{CS0}$ for boot.	
P2.28/D28	17 <sup>[5]</sup>	G2[5]	I/O	<b>D28</b> — External memory data line 28.	
P2.29/D29	18 <sup>[5]</sup>	G1 <u>5</u>	I/O	<b>D29</b> — External memory data line 29.	
P2.30/D30/	19 <sup>[2]</sup>	G3[2]	I/O	<b>D30</b> — External memory data line 30.	
AIN4			I	<b>AIN4</b> — ADC, input 4. This analog input is always connected to its pin.	
P2.31/D31/	20[2]	20 <sup>[2]</sup> G4 <sup>[2]</sup>	G4[2]	I/O	D31 — External memory data line 31.
AIN5			I	<b>AIN5</b> — ADC, input 5. This analog input is always connected to its pin.	
P3.0 to P3.31			I/O	<b>Port 3</b> — Port 3 is a 32-bit bidirectional I/O port with individual direction controls for each bit. The operation of port 3 pins depends upon the pin function selected via the Pin Connect Block.	
P3.0/A0	89 <u>[5]</u>	G12 <sup>[5]</sup>	0	A0 — External memory address line 0.	
P3.1/A1	88 <mark>[5]</mark>	H13 <sup>[5]</sup>	0	A1 — External memory address line 1.	
P3.2/A2	87 <mark>[5]</mark>	H12 <sup>[5]</sup>	0	A2 — External memory address line 2.	
P3.3/A3	81 <sup>[5]</sup>	J10 <sup>[5]</sup>	0	A3 — External memory address line 3.	
P3.4/A4	80 <mark>[5]</mark>	K13 <sup>[5]</sup>	0	A4 — External memory address line 4.	
P3.5/A5	74 <sup>[5]</sup>	M13 <sup>[5]</sup>	0	A5 — External memory address line 5.	
P3.6/A6	73 <sup>[5]</sup>	N13 <sup>[5]</sup>	0	A6 — External memory address line 6.	
P3.7/A7	72 <sup>[5]</sup>	M12 <sup>[5]</sup>	0	A7 — External memory address line 7.	
P3.8/A8	71 <sup>[5]</sup>	N12 <sup>[5]</sup>	0	A8 — External memory address line 8.	
P3.9/A9	66 <sup>[5]</sup>	M10 <sup>[5]</sup>	0	A9 — External memory address line 9.	
P3.10/A10	65 <sup>[5]</sup>	N10 <sup>[5]</sup>	0	A10 — External memory address line 10.	
P3.11/A11	64 <mark>[5]</mark>	K9[5]	0	A11 — External memory address line 11.	
P3.12/A12	63 <mark>[5]</mark>	L9[5]	0	A12 — External memory address line 12.	
P3.13/A13	62 <sup>[5]</sup>	M9[5]	0	A13 — External memory address line 13.	
P3.14/A14	56 <sup>[5]</sup>	K7[5]	0	A14 — External memory address line 14.	
P3.15/A15	55 <mark>[5]</mark>	L7 <sup>[5]</sup>	0	A15 — External memory address line 15.	
				•	
	53 <mark>[5]</mark>	M7 <sup>[5]</sup>	0	A16 — External memory address line 16.	
P3.16/A16 P3.17/A17	53 <sup>[5]</sup> 48 <sup>[5]</sup>	M7 <sup>[5]</sup>	0	A16 — External memory address line 16.  A17 — External memory address line 17.	

 Table 4.
 Pin description ...continued

Symbol	Pin (LQFP)	Pin (TFBGA)	Tyne	Description
P3.19/A19	46 <sup>[5]</sup>	L5[5]	О	•
P3.19/A19 P3.20/A20	45 <u>[5]</u>	K5[5]	0	A19 — External memory address line 19.
P3.21/A21	45 <u>6</u> 44 <u>[5]</u>	N4 <u>5</u>	0	<ul><li>A20 — External memory address line 20.</li><li>A21 — External memory address line 21.</li></ul>
P3.22/A22	41[5]	K4 <u>5</u>	0	
	41 <u>5</u>	N3[5]		A22 — External memory address line 22.
P3.23/A23/ XCLK	40⊡	IN2	0	A23 — External memory address line 23.  XCLK — Clock output.
	20[5]	M2 <sup>[5]</sup>	0	•
P3.24/CS3	36 <u>[5]</u>	IVI2 <u>©</u>	0	CS3 — LOW-active Chip Select 3 signal.  (Bank 3 addresses range 0x8300 0000 to 0x83FF FFFF)
P3.25/CS2	35 <u>[5]</u>	M1[5]	0	CS2 — LOW-active Chip Select 2 signal.
F3.25/C32	30 <u>61</u>	IVI I	O	(Bank 2 addresses range 0x8200 0000 to 0x82FF FFFF)
P3.26/CS1	30[5]	K2[5]	0	CS1 — LOW-active Chip Select 1 signal.
F3.20/C31	30⊡	NZ <u>⊡</u>	O	(Bank 1 addresses range 0x8100 0000 to 0x81FF FFFF)
P3.27/WE	29 <mark>[5]</mark>	K1 <u>5</u>	0	WE — LOW-active Write enable signal.
P3.28/BLS3/	28[2]	J4[2]	0	BLS3 — LOW-active Write enable signal.  BLS3 — LOW-active Byte Lane Select signal (Bank 3).
AIN7	2011	J4 <u>1-1</u>	<u> </u>	• • • • • • • • • • • • • • • • • • • •
			ı	<b>AIN7</b> — ADC, input 7. This analog input is always connected to its pin.
P3.29/BLS2/	27 <u>[4]</u>	J3 <mark>[4]</mark>	0	BLS2 — LOW-active Byte Lane Select signal (Bank 2).
AIN6			I	<b>AIN6</b> — ADC, input 6. This analog input is always connected to its pin.
P3.30/BLS1	97 <mark>[4]</mark>	E13[4]	0	BLS1 — LOW-active Byte Lane Select signal (Bank 1).
P3.31/BLS0	96 <mark>[4]</mark>	F10[4]	0	BLS0 — LOW-active Byte Lane Select signal (Bank 0).
n.c.	22[5]	H2 <sup>[5]</sup>		Not connected. This pin MUST NOT be pulled LOW or the device might not operate properly.
RESET	135 <u><sup>[6]</sup></u>	C5[6]	I	<b>External reset input:</b> A LOW on this pin resets the device, causing I/O ports and peripherals to take on their default states, and processor execution to begin at address 0. TTL with hysteresis, 5 V tolerant.
XTAL1	142 <u>[7]</u>	C3[7]	I	Input to the oscillator circuit and internal clock generator circuits.
XTAL2	141[7]	B3[7]	0	Output from the oscillator amplifier.
V <sub>SS</sub>	3, 9, 26, 38, 54, 67, 79, 93, 103, 107, 111, 128	C2, E4, J2, N2, N7, L10, K12, F13, D11, B13, B11, D7	I	Ground: 0 V reference.
V <sub>SSA</sub>	139	C4	I	<b>Analog ground:</b> 0 V reference. This should nominally be the same voltage as $V_{SS}$ , but should be isolated to minimize noise and error.
V <sub>SSA(PLL)</sub>	138	B4	I	<b>PLL analog ground:</b> 0 V reference. This should nominally be the same voltage as $V_{\rm SS}$ , but should be isolated to minimize noise and error.
$V_{DD(1V8)}$	37, 110	N1, A12	I	<b>1.8 V core power supply:</b> This is the power supply voltage for internal circuitry.

Table 4. Pin description ... continued

Symbol	Pin (LQFP)	Pin (TFBGA)	Туре	Description
V <sub>DDA(1V8)</sub>	143	A2	I	<b>Analog 1.8 V core power supply:</b> This is the power supply voltage for internal circuitry. This should be nominally the same voltage as $V_{DD(1V8)}$ but should be isolated to minimize noise and error.
V <sub>DD(3V3)</sub>	2, 31, 39, 51, 57, 77, 94, 104, 112, 119	M6, N8, K10,	I	<b>3.3 V pad power supply:</b> This is the power supply voltage for the I/O ports.
V <sub>DDA(3V3)</sub>	14	F3	I	<b>Analog 3.3 V pad power supply:</b> This should be nominally the same voltage as $V_{DD(3V3)}$ but should be isolated to minimize noise and error.

- [1] 5 V tolerant pad providing digital I/O functions with TTL levels and hysteresis and 10 ns slew rate control.
- [2] 5 V tolerant pad providing digital I/O functions with TTL levels and hysteresis and 10 ns slew rate control. If configured for an input function, this pad utilizes built-in glitch filter that blocks pulses shorter than 3 ns.
- [3] Open drain 5 V tolerant digital I/O I<sup>2</sup>C-bus 400 kHz specification compatible pad. It requires external pull-up to provide an output functionality.
- [4] 5 V tolerant pad providing digital I/O (with TTL levels and hysteresis and 10 ns slew rate control) and analog input function. If configured for a digital input function, this pad utilizes built-in glitch filter that blocks pulses shorter than 3 ns. When configured as an ADC input, digital section of the pad is disabled.
- [5] 5 V tolerant pad with built-in pull-up resistor providing digital I/O functions with TTL levels and hysteresis and 10 ns slew rate control. The pull-up resistor's value ranges from  $60 \text{ k}\Omega$  to  $300 \text{ k}\Omega$ .
- [6] 5 V tolerant pad providing digital input (with TTL levels and hysteresis) function only.
- [7] Pad provides special analog functionality.

# 6. Functional description

### 6.1 Architectural overview

The ARM7TDMI-S is a general purpose 32-bit microprocessor, which offers high performance and very low power consumption. The ARM architecture is based on RISC principles, and the instruction set and related decode mechanism are much simpler than those of microprogrammed CISC. This simplicity results in a high instruction throughput and impressive real-time interrupt response from a small and cost-effective processor core.

Pipeline techniques are employed so that all parts of the processing and memory systems can operate continuously. Typically, while one instruction is being executed, its successor is being decoded, and a third instruction is being fetched from memory.

The ARM7TDMI-S processor also employs a unique architectural strategy known as Thumb, which makes it ideally suited to high-volume applications with memory restrictions, or applications where code density is an issue.

The key idea behind Thumb is that of a super-reduced instruction set. Essentially, the ARM7TDMI-S processor has two instruction sets:

- The standard 32-bit ARM set.
- A 16-bit Thumb set.

The Thumb set's 16-bit instruction length allows it to approach twice the density of standard ARM code while retaining most of the ARM's performance advantage over a traditional 16-bit processor using 16-bit registers. This is possible because Thumb code operates on the same 32-bit register set as ARM code.

Thumb code is able to provide up to 65 % of the code size of ARM, and 160 % of the performance of an equivalent ARM processor connected to a 16-bit memory system.

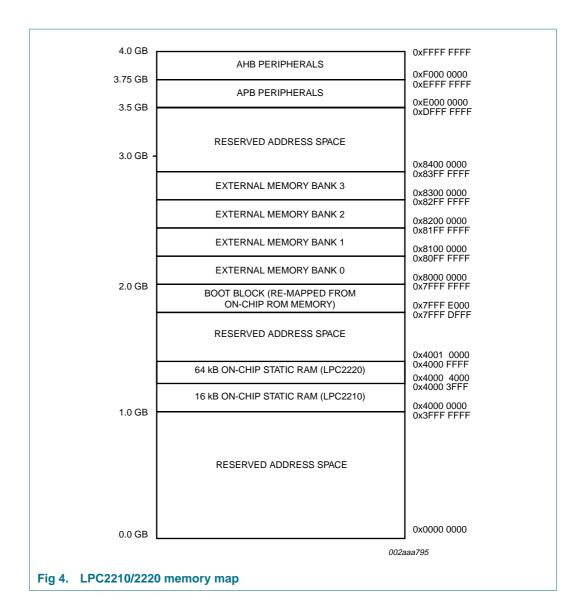
# 6.2 On-chip SRAM

On-chip SRAM may be used for code and/or data storage. The SRAM may be accessed as 8-bit, 16-bit, and 32-bit. The LPC2210 and LPC2210/01 provide 16 kB of static RAM, and the LPC2220 provides 64 kB of static RAM.

# 6.3 Memory map

The LPC2210/2220 memory maps incorporate several distinct regions, as shown in Figure 4.

In addition, the CPU interrupt vectors may be re-mapped to allow them to reside in either on-chip bootloader, external memory BANK0 or on-chip static RAM. This is described in Section 6.20 "System control".



# 6.4 Interrupt controller

The VIC accepts all of the interrupt request inputs and categorizes them as Fast Interrupt Request (FIQ), vectored Interrupt Request (IRQ), and non-vectored IRQ as defined by programmable settings. The programmable assignment scheme means that priorities of interrupts from the various peripherals can be dynamically assigned and adjusted.

FIQ has the highest priority. If more than one request is assigned to FIQ, the VIC combines the requests to produce the FIQ signal to the ARM processor. The fastest possible FIQ latency is achieved when only one request is classified as FIQ, because then the FIQ service routine can simply start dealing with that device. But if more than one request is assigned to the FIQ class, the FIQ service routine can read a word from the VIC that identifies which FIQ source(s) is (are) requesting an interrupt.

Vectored IRQs have the middle priority. Sixteen of the interrupt requests can be assigned to this category. Any of the interrupt requests can be assigned to any of the 16 vectored IRQ slots, among which slot 0 has the highest priority and slot 15 has the lowest.

Non-vectored IRQs have the lowest priority.

The VIC combines the requests from all the vectored and non-vectored IRQs to produce the IRQ signal to the ARM processor. The IRQ service routine can start by reading a register from the VIC and jumping there. If any of the vectored IRQs are requesting, the VIC provides the address of the highest-priority requesting IRQs service routine, otherwise it provides the address of a default routine that is shared by all the non-vectored IRQs. The default routine can read another VIC register to see what IRQs are active.

#### 6.4.1 Interrupt sources

<u>Table 5</u> lists the interrupt sources for each peripheral function. Each peripheral device has one interrupt line connected to the VIC, but may have several internal interrupt flags. Individual interrupt flags may also represent more than one interrupt source.

Table 5. Interrupt sources

Block	Flag(s)	VIC channel #
WDT	Watchdog Interrupt (WDINT)	0
-	Reserved for software interrupts only	1
ARM Core	EmbeddedICE, DbgCommRX	2
ARM Core	EmbeddedICE, DbgCommTX	3
TIMER0	Match 0 to 3 (MR0, MR1, MR2, MR3)	4
TIMER1	Match 0 to 3 (MR0, MR1, MR2, MR3)	5
UART0	RX Line Status (RLS)	6
	Transmit Holding Register Empty (THRE)	
	RX Data Available (RDA)	
	Character Time-out Indicator (CTI)	
UART1	RX Line Status (RLS)	7
	Transmit Holding Register empty (THRE)	
	RX Data Available (RDA)	
	Character Time-out Indicator (CTI)	
	Modem Status Interrupt (MSI)	
PWM0	Match 0 to 6 (MR0, MR1, MR2, MR3, MR4, MR5, MR6)	8
I <sup>2</sup> C	SI (state change)	9
SPI0	SPIF, MODF	10
SPI1 and SSP	SPIF, MODF and TXRIS, RXRIS, RTRIS, RORRIS	11
PLL	PLL Lock (PLOCK)	12
RTC	RTCCIF (Counter Increment), RTCALF (Alarm)	13
System Control	External Interrupt 0 (EINT0)	14
	External Interrupt 1 (EINT1)	15
	External Interrupt 2 (EINT2)	16
	External Interrupt 3 (EINT3)	17
A/D	ADC	18

#### 6.5 Pin connect block

The pin connect block allows selected pins of the microcontroller to have more than one function. Configuration registers control the multiplexers to allow connection between the pin and the on chip peripherals. Peripherals should be connected to the appropriate pins prior to being activated, and prior to any related interrupt(s) being enabled. Activity of any enabled peripheral function that is not mapped to a related pin should be considered undefined.

The pin control module contains three registers as shown in Table 6.

Table 6. Pin control module registers

Address	Name	Description	Access
0xE002 C000	PINSEL0	pin function select register 0	read/write
0xE002 C004	PINSEL1	pin function select register 1	read/write
0xE002 C014	PINSEL2	pin function select register 2	read/write

# 6.6 Pin function select register 0 (PINSEL0 - 0xE002 C000)

The PINSEL0 register controls the functions of the pins as per the settings listed in Table 7. The direction control bit in the IODIR register is effective only when the GPIO function is selected for a pin. For other functions, direction is controlled automatically. Settings other than those shown in Table 7 are reserved, and should not be used

Table 7. Pin function select register 0 (PINSEL0 - 0xE002 C000)

PINSEL0	Pin name	Value		Function	Value after reset
1:0	P0.0	0	0	GPIO Port 0.0	0
		0	1	TXD0 (UART0)	
		1	0	PWM1	
		1	1	reserved	
3:2	P0.1	0	0	GPIO Port 0.1	0
		0	1	RXD0 (UART0)	
		1	0	PWM3	
		1	1	EINT0	
5:4	P0.2	0	0	GPIO Port 0.2	0
		0	1	SCL (I <sup>2</sup> C-bus)	
		1	0	Capture 0.0 (Timer 0)	
		1	1	reserved	
7:6	P0.3	0	0	GPIO Port 0.3	0
		0	1	SDA (I <sup>2</sup> C-bus)	
		1	0	Match 0.0 (Timer 0)	
		1	1	EINT1	
9:8	P0.4		0	GPIO Port 0.4	0
		0	1	SCK (SPI0)	
		1	0	Capture 0.1 (Timer 0)	
		1	1	reserved	

Table 7. Pin function select register 0 (PINSEL0 - 0xE002 C000) ...continued

PINSEL0	Pin name	Value		Function	Value after reset
11:10	P0.5	0	0	GPIO Port 0.5	0
		0	1	MISO (SPI0)	
		1	0	Match 0.1 (Timer 0)	
		1	1	reserved	
13:12	P0.6	0	0	GPIO Port 0.6	0
		0	1	MOSI (SPI0)	
		1	0	Capture 0.2 (Timer 0)	
		1	1	reserved	
15:14	P0.7	0	0	GPIO Port 0.7	0
		0	1	SSEL (SPI0)	
		1	0	PWM2	
		1	1	EINT2	
17:16	P0.8	0	0	GPIO Port 0.8	0
		0	1	TXD1 UART1	
		1	0	PWM4	
		1	1	reserved	
19:18	P0.9	0	0	GPIO Port 0.9	0
		0	1	RXD1 (UART1)	
		1	0	PWM6	
		1	1	EINT3	
21:20	P0.10	0	0	GPIO Port 0.10	0
		0	1	RTS1 (UART1)	
		1	0	Capture 1.0 (Timer 1)	
		1	1	reserved	
23:22	P0.11	0	0	GPIO Port 0.11	0
		0	1	CTS1 (UART1)	
		1	0	Capture 1.1 (Timer 1)	
		1	1	reserved	
25:24	P0.12	0	0	GPIO Port 0.12	0
		0	1	DSR1 (UART1)	
		1	0	Match 1.0 (Timer 1)	
		1	1	reserved	
27:26	P0.13	0	0	GPIO Port 0.13	0
		0	1	DTR1 (UART1)	
		1	0	Match 1.1 (Timer 1)	
		1	1	reserved	
29:28	P0.14	0	0	GPIO Port 0.14	0
		0	1	DCD1 (UART1)	
		1	0	EINT1	
		1	1	reserved	

Table 7. Pin function select register 0 (PINSEL0 - 0xE002 C000) ...continued

PINSEL0	Pin name	Value		Function	Value after reset
31:30	P0.15	0	0	GPIO Port 0.15	0
		0	1	RI1 (UART1)	
		1	0	EINT2	
		1	1	reserved	

# 6.7 Pin function select register 1 (PINSEL1 - 0xE002 C004)

The PINSEL1 register controls the functions of the pins as per the settings listed in Table 8. The direction control bit in the IODIR register is effective only when the GPIO function is selected for a pin. For other functions direction is controlled automatically. Settings other than those shown in the Table 8 are reserved, and should not be used.

Table 8. Pin function select register 1 (PINSEL1 - 0xE002 C004)

PINSEL1	Pin name	Value		Function	Value after reset
1:0	P0.16	0	0	GPIO Port 0.16	0
		0	1	EINT0	
		1	0	Match 0.2 (Timer 0)	
		1	1	Capture 0.2 (Timer 0)	
3:2	P0.17	0	0	GPIO Port 0.17	0
		0	1	Capture 1.2 (Timer 1)	
		1	0	SCK (SPI1)	
		1	1	Match 1.2 (Timer 1)	
5:4	P0.18	0	0	GPIO Port 0.18	0
		0	1	Capture 1.3 (Timer 1)	
		1	0	MISO (SPI1)	
		1	1	Match 1.3 (Timer 1)	
7:6	P0.19	0	0	GPIO Port 0.19	0
		0	1	Match 1.2 (Timer 1)	
		1	0	MOSI (SPI1)	
		1	1	Capture 1.2 (Timer 1)	
9:8	P0.20	0	0	GPIO Port 0.20	0
		0	1	Match 1.3 (Timer 1)	
		1	0	SSEL (SPI1)	
		1	1	EINT3	
11:10	P0.21	0	0	GPIO Port 0.21	0
		0	1	PWM5	
		1	0	reserved	
		1	1	Capture 1.3 (Timer 1)	
13:12	P0.22	0	0	GPIO Port 0.22	0
		0	1	reserved	
		1	0	Capture 0.0 (Timer 0)	
		1	1	Match 0.0 (Timer 0)	

Table 8. Pin function select register 1 (PINSEL1 - 0xE002 C004) ...continued

PINSEL1	Pin name	Value		Function	Value after reset
15:14	P0.23	0	0	GPIO Port 0.23	0
		0	1	reserved	
		1	0	reserved	
		1	1	reserved	
17:16	P0.24	0	0	GPIO Port 0.24	0
		0	1	reserved	
		1	0	reserved	
		1	1	reserved	
19:18	P0.25	0	0	GPIO Port 0.25	0
		0	1	reserved	
		1	0	reserved	
		1	1	reserved	
21:20	P0.26	0	0	reserved	0
		0	1	reserved	
		1	0	reserved	
		1	1	reserved	
23:22	P0.27	0	0	GPIO Port 0.27	1
		0	1	AIN0 (A/D input 0)	
		1	0	Capture 0.1 (Timer 0)	
		1	1	Match 0.1 (Timer 0)	
25:24	P0.28	0	0	GPIO Port 0.28	1
		0	1	AIN1 (A/D input 1)	
		1	0	Capture 0.2 (Timer 0)	
		1	1	Match 0.2 (Timer 0)	
27:26	P0.29	0	0	GPIO Port 0.29	1
		0	1	AIN2 (A/D input 2)	
		1	0	Capture 0.3 (Timer 0)	
		1	1	Match 0.3 (Timer 0)	
29:28	P0.30	0	0	GPIO Port 0.30	1
		0	1	AIN3 (A/D input 0)	
		1	0	EINT3	
		1	1	Capture 0.0 (Timer 0)	
31:30 P0.31		0	0	reserved	0
31:30	1 0.01				
31:30	1 0.01	0	1	reserved	
31:30	1 0.01	0	1	reserved reserved	

# 6.8 Pin function select register 2 (PINSEL2 - 0xE002 C014)

The PINSEL2 register controls the functions of the pins as per the settings listed in Table 9. The direction control bit in the IODIR register is effective only when the GPIO function is selected for a pin. For other functions direction is controlled automatically. Settings other than those shown in Table 9 are reserved, and should not be used.

Table 9. Pin function select register 2 (PINSEL2 - 0xE002 C014)

PINSEL2 bits	Description				Reset value		
1:0	reserved				-		
2	When 0, pins P1[3 Debug port.	When 0, pins P1[36:26] are used as GPIO pins. When 1, P1[31:26] are used as a Debug port.					
3	When 0, pins P1[2 Trace port.	5:16] are used as 0	SPIO pins. When	1, P1[25:16] are used as a	P1.20/ TRACESYNC		
5:4	Controls the use o	f the data bus and s	strobe pins:		BOOT1:0		
	Pins P2[7:0]	11 = P2[7	:0]	0x  or  10 = D7  to  D0			
	Pin P1.0	11 = P1.0		$0x \text{ or } 10 = \overline{CSO}$			
	Pin P1.1	11 = P1.1		$0x \text{ or } 10 = \overline{OE}$			
	Pin P3.31	11 = P3.3	1	$0x \text{ or } 10 = \overline{BLS0}$			
	Pins P2[15:8]	00 or 11 = P2[1	5:8]	01 or 10 = D15 to D8			
	Pin P3.30	00 or 11 = P3.3	0	$01 \text{ or } 10 = \overline{BLS1}$			
	Pins P2[27:16]	0x  or  11 = P2[2]	7:16]	10 = D27 to D16			
	Pins P2[29:28]	0x  or  11 = P2[2]	9:28]	10 = D29, D28			
	Pins P2[31:30]	0x or 11 = P2[3 AIN4	1:30] or AIN5 to	10 = D31, D30			
	Pins P3[29:28]	0x or 11 = P3[2 AIN6	9:28] or AIN7 to	$10 = \overline{BLS2}, \overline{BLS3}$			
6	If bits 5:4 are not 1 AIN6.	1					
7	If bits 5:4 are not 1 AIN7.	0, controls the use	of pin P3.28: 0 er	nables P3.28, 1 enables	1		
8	Controls the use of	f pin P3.27: 0 enab	es P3.27, 1 enabl	es WE.	0		
10:9	reserved				-		
11	Controls the use o	f pin P3.26: 0 enab	es P3.26, 1 enabl	es CS1.	0		
12	reserved				-		
13	If bits 27:25 are no 1 enables XCLK.	t 111, controls the u	se of pin P3.23/A	23/XCLK: 0 enables P3.23,	0		
15:14	Controls the use o reserved values.	f pin P3.25: 00 ena	oles P3.25, 01 en	ables $\overline{\text{CS2}}$ , 10 and 11 are	00		
17:16	Controls the use o reserved values.	f pin P3.24: 00 ena	oles P3.24, 01 en	ables $\overline{\text{CS3}}$ , 10 and 11 are	00		
19:18	reserved				-		
20	If bits 5:4 are not 1 reserved	0, controls the use	of pin P2[29:28]:	0 enables P2[29:28], 1 is	0		
21	If bits 5:4 are not 1 AIN4.	0, controls the use	of pin P2.30: 0 er	nables P2.30, 1 enables	1		
22	If bits 5:4 are not 1 AIN5.	0, controls the use	of pin P2.31: 0 er	nables P2.31, 1 enables	1		

Table 9. Pin function select register 2 (PINSEL2 - 0xE002 C014) ...continued

PINSEL2 bits	Description		Reset value
23	Controls whether P3.0/A0 is a	1 if BOOT1:0 = 00 at RESET = 0, 0 otherwise	
24	Controls whether P3.1/A1 is a	BOOT1 during reset	
27:25	Controls the number of pins a are address lines:	000 if BOOT1:0 = 11 at	
	000 = None	100 = A11 to A2 are address lines.	reset, 111  otherwise
	001 = A3 to A2 are address 101 = A15 to A2 are address lines.		— oti lei wise
	010 = A5 to A2 are address 110 = A19 to A2 are address lines.		
	011 = A7 to A2 are address lines.		
31:28	reserved		

# 6.9 External memory controller

The external static memory controller is a module which provides an interface between the system bus and external (off-chip) memory devices. It provides support for up to four independently configurable memory banks (16 MB each with byte lane enable control) simultaneously. Each memory bank is capable of supporting SRAM, ROM, flash EPROM, burst ROM memory, or some external I/O devices.

Each memory bank may be 8-bit, 16-bit, or 32-bit wide.

# 6.10 General purpose parallel I/O

Device pins that are not connected to a specific peripheral function are controlled by the GPIO registers. Pins may be dynamically configured as inputs or outputs. Separate registers allow setting or clearing any number of outputs simultaneously. The value of the output register may be read back, as well as the current state of the port pins.

#### 6.10.1 Features

- Direction control of individual bits.
- · Separate control of output set and clear.
- All I/O default to inputs after reset.

### 6.11 10-bit ADC

The LPC2210/2220 each contain a single 10-bit successive approximation ADC with eight multiplexed channels.

#### 6.11.1 Features

- Measurement range of 0 V to 3 V.
- Capable of performing more than 400000 10-bit samples per second.
- Burst conversion mode for single or multiple inputs.

Optional conversion on transition on input pin or Timer Match signal.

# 6.11.2 ADC features available in LPC2210/01 and LPC2220 only

- Every analog input has a dedicated result register to reduce interrupt overhead.
- Every analog input can generate an interrupt once the conversion is completed.
- The ADC pads are 5 V tolerant when configured for digital I/O function(s).

# **6.12 UARTs**

The LPC2210/2220 each contain two UARTs. One UART provides a full modem control handshake interface, the other provides only transmit and receive data lines.

#### 6.12.1 Features

- 16 B receive and transmit FIFOs.
- Register locations conform to 16C550 industry standard.
- Receiver FIFO trigger points at 1 B, 4 B, 8 B, and 14 B.
- Built-in baud rate generator.
- Standard modem interface signals included on UART1.

#### 6.12.2 UART features available in LPC2210/01 and LPC2220 only

Compared to previous LPC2000 microcontrollers, UARTs in LPC2210/01 and LPC2220 introduce a fractional baud rate generator for both UARTs, enabling these microcontrollers to achieve standard baud rates such as 115200 Bd with any crystal frequency above 2 MHz. In addition, auto-CTS/RTS flow-control functions are fully implemented in hardware.

- Fractional baud rate generator enables standard baud rates such as 115200 Bd to be achieved with any crystal frequency above 2 MHz.
- Auto-bauding.
- Auto-CTS/RTS flow-control fully implemented in hardware.

### 6.13 I<sup>2</sup>C-bus serial I/O controller

The I<sup>2</sup>C-bus is bidirectional for inter-IC control using only two wires: a serial clock line (SCL), and a serial data line (SDA). Each device is recognized by a unique address and can operate as either a receiver-only device (e.g., an LCD driver or a transmitter with the capability to both receive and send information (such as memory). Transmitters and/or receivers can operate in either master or slave mode, depending on whether the chip has to initiate a data transfer or is only addressed. The I<sup>2</sup>C-bus is a multi-master bus, and it can be controlled by more than one bus master connected to it.

The  $I^2C$ -bus implemented in LPC2210/2220 supports a bit rate up to 400 kbit/s (fast  $I^2C$ -bus).

### 6.13.1 Features

- Compliant with standard I<sup>2</sup>C-bus interface.
- Easy to configure as master, slave, or master/slave.

- Programmable clocks allow versatile rate control.
- Bidirectional data transfer between masters and slaves.
- Multi-master bus (no central master).
- Arbitration between simultaneously transmitting masters without corruption of serial data on the bus.
- Serial clock synchronization allows devices with different bit rates to communicate via one serial bus.
- Serial clock synchronization can be used as a handshake mechanism to suspend and resume serial transfer.
- The I<sup>2</sup>C-bus may be used for test and diagnostic purposes.

#### 6.14 SPI serial I/O controller

The LPC2210/2220 each contain two SPIs. The SPI is a full duplex serial interface, designed to be able to handle multiple masters and slaves connected to a given bus. Only a single master and a single slave can communicate on the interface during a given data transfer. During a data transfer the master always sends a byte of data to the slave, and the slave always sends a byte of data to the master.

#### 6.14.1 Features

- Compliant with SPI specification.
- Synchronous, serial, full duplex, communication.
- · Combined SPI master and slave.
- Maximum data bit rate of one eighth of the input clock rate.

#### 6.15 SSP controller

This peripheral is available in LPC2210/01 and LPC2220 only.

# 6.15.1 Features

- Compatible with Motorola's SPI, Texas Instrument's 4-wire SSI, and National Semiconductor's Microwire buses.
- Synchronous serial communication.
- Master or slave operation.
- 8-frame FIFOs for both transmit and receive.
- 4 bits to 16 bits per frame.

#### 6.15.2 Description

The SSP is a controller capable of operation on a SPI, 4-wire SSI, or Microwire bus. It can interact with multiple masters and slaves on the bus. Only a single master and a single slave can communicate on the bus during a given data transfer. Data transfers are in principle full duplex, with frames of 4 bits to 16 bits of data flowing from the master to the slave and from the slave to the master.

While the SSP and SPI1 peripherals share the same physical pins, it is not possible to have both of these two peripherals active at the same time. Application can switch on the fly from SPI1 to SSP and back.

# 6.16 General purpose timers

The timer/counter is designed to count cycles of the peripheral clock (PCLK) or an externally supplied clock and optionally generate interrupts or perform other actions at specified timer values, based on four match registers. It also includes four capture inputs to trap the timer value when an input signal transitions, optionally generating an interrupt. Multiple pins can be selected to perform a single capture or match function, providing an application with 'or' and 'and', as well as 'broadcast' functions among them.

#### 6.16.1 Features

- A 32-bit timer/counter with a programmable 32-bit prescaler.
- Timer operation (LPC2210/2220) or external event counter (LPC2210/01 and LPC2220 only).
- Four 32-bit capture channels per timer/counter that can take a snapshot of the timer value when an input signal transitions. A capture event may also optionally generate an interrupt.
- Four 32-bit match registers that allow:
  - Continuous operation with optional interrupt generation on match.
  - Stop timer on match with optional interrupt generation.
  - Reset timer on match with optional interrupt generation.
- Four external outputs per timer/counter corresponding to match registers, with the following capabilities:
  - Set LOW on match.
  - Set HIGH on match.
  - Toggle on match.
  - Do nothing on match.

### 6.16.2 Features available in LPC2210/01 and LPC2220 only

The LPC2210/01 and LPC2220 can count external events on one of the capture inputs if the external pulse lasts at least one half of the period of the PCLK. In this configuration, unused capture lines can be selected as regular timer capture inputs or used as external interrupts.

- Timer can count cycles of either the peripheral clock (PCLK) or an externally supplied clock.
- When counting cycles of an externally supplied clock, only one of the timer's capture
  inputs can be selected as the timer's clock. The rate of such a clock is limited to
  PCLK / 4. Duration of high/low levels on the selected capture input cannot be shorter
  than 1 / (2PCLK).

# 6.17 Watchdog timer

The purpose of the watchdog is to reset the microcontroller within a reasonable amount of time if it enters an erroneous state. When enabled, the watchdog will generate a system reset if the user program fails to 'feed' (or reload) the watchdog within a predetermined amount of time.

#### **6.17.1** Features

- · Internally resets chip if not periodically reloaded.
- Debug mode.
- Enabled by software but requires a hardware reset or a watchdog reset/interrupt to be disabled.
- Incorrect/incomplete feed sequence causes reset/interrupt if enabled.
- Flag to indicate watchdog reset.
- Programmable 32-bit timer with internal prescaler.
- Selectable time period from (T<sub>cy(PCLK)</sub> × 256 × 4) to (T<sub>cy(PCLK)</sub> × 2<sup>32</sup> × 4) in multiples of T<sub>cy(PCLK)</sub> × 4.

#### 6.18 Real-time clock

The Real-Time Clock (RTC) is designed to provide a set of counters to measure time when normal or idle operating mode is selected. The RTC has been designed to use little power, making it suitable for battery powered systems where the CPU is not running continuously (Idle mode).

### 6.18.1 Features

- Measures the passage of time to maintain a calendar and clock.
- Ultra-low power design to support battery powered systems.
- Provides Seconds, Minutes, Hours, Day of Month, Month, Year, Day of Week, and Day of Year.
- Programmable reference clock divider allows adjustment of the RTC to match various crystal frequencies.

#### 6.19 Pulse width modulator

The PWM is based on the standard timer block and inherits all of its features, although only the PWM function is pinned out on the LPC2210/2220. The timer is designed to count cycles of the peripheral clock (PCLK) and optionally generate interrupts or perform other actions when specified timer values occur, based on seven match registers. The PWM function is also based on match register events.

The ability to separately control rising and falling edge locations allows the PWM to be used for more applications. For instance, multi-phase motor control typically requires three non-overlapping PWM outputs with individual control of all three pulse widths and positions.

Two match registers can be used to provide a single edge controlled PWM output. One match register (MR0) controls the PWM cycle rate, by resetting the count upon match. The other match register controls the PWM edge position. Additional single edge

controlled PWM outputs require only one match register each, since the repetition rate is the same for all PWM outputs. Multiple single edge controlled PWM outputs will all have a rising edge at the beginning of each PWM cycle, when an MR0 match occurs.

Three match registers can be used to provide a PWM output with both edges controlled. Again, the MR0 match register controls the PWM cycle rate. The other match registers control the two PWM edge positions. Additional double edge controlled PWM outputs require only two match registers each, since the repetition rate is the same for all PWM outputs.

With double edge controlled PWM outputs, specific match registers control the rising and falling edge of the output. This allows both positive going PWM pulses (when the rising edge occurs prior to the falling edge), and negative going PWM pulses (when the falling edge occurs prior to the rising edge).

#### 6.19.1 Features

- Seven match registers allow up to six single edge controlled or three double edge controlled PWM outputs, or a mix of both types.
- The match registers also allow:
  - Continuous operation with optional interrupt generation on match.
  - Stop timer on match with optional interrupt generation.
  - Reset timer on match with optional interrupt generation.
- Supports single edge controlled and/or double edge controlled PWM outputs. Single
  edge controlled PWM outputs all go HIGH at the beginning of each cycle unless the
  output is a constant LOW. Double edge controlled PWM outputs can have either edge
  occur at any position within a cycle. This allows for both positive going and negative
  going pulses.
- Pulse period and width can be any number of timer counts. This allows complete
  flexibility in the trade-off between resolution and repetition rate. All PWM outputs will
  occur at the same repetition rate.
- Double edge controlled PWM outputs can be programmed to be either positive going or negative going pulses.
- Match register updates are synchronized with pulse outputs to prevent generation of erroneous pulses. Software must 'release' new match values before they can become effective.
- May be used as a standard timer if the PWM mode is not enabled.
- A 32-bit timer/counter with a programmable 32-bit prescaler.

# 6.20 System control

# 6.20.1 Crystal oscillator

The oscillator supports crystals in the range of 1 MHz to 25 MHz and up to 25 MHz with the external oscillator. The oscillator output frequency is called  $f_{\rm osc}$  and the ARM processor clock frequency is referred to as CCLK for purposes of rate equations, etc.  $f_{\rm osc}$  and CCLK are the same value unless the PLL is running and connected. Refer to Section 6.20.2 "PLL" for additional information.

#### 6.20.2 PLL

The PLL accepts an input clock frequency in the range of 10 MHz to 25 MHz. The input frequency is multiplied up into the range of 10 MHz to 60 MHz (LPC2210) and 10 MHz to 75 MHz (LPC2210/01 and LPC2220) with a Current Controlled Oscillator (CCO). The multiplier can be an integer value from 1 to 32 (in practice, the multiplier value cannot be higher than 6 on this family of microcontrollers due to the upper frequency limit of the CPU). The CCO operates in the range of 156 MHz to 320 MHz, so there is an additional divider in the loop to keep the CCO within its frequency range while the PLL is providing the desired output frequency. The output divider may be set to divide by 2, 4, 8, or 16 to produce the output clock. Since the minimum output divider value is 2, it is insured that the PLL output has a 50 % duty cycle. The PLL is turned off and bypassed following a chip reset and may be enabled by software. The program must configure and activate the PLL, wait for the PLL to Lock, then connect to the PLL as a clock source. The PLL settling time is 100  $\mu s$ .

#### 6.20.3 Reset and wake-up timer

Reset has two sources on the LPC2210/2220: the RESET pin and watchdog reset. The RESET pin is a Schmitt trigger input pin with an additional glitch filter. Assertion of chip reset by any source starts the wake-up timer (see wake-up timer description below), causing the internal chip reset to remain asserted until the external reset is de-asserted, the oscillator is running, a fixed number of clocks have passed, and the on-chip circuitry has completed its initialization.

When the internal reset is removed, the processor begins executing at address 0, which is the reset vector. At that point, all of the processor and peripheral registers have been initialized to predetermined values.

The wake-up timer ensures that the oscillator and other analog functions required for chip operation are fully functional before the processor is allowed to execute instructions. This is important at power-on, all types of reset, and whenever any of the aforementioned functions are turned off for any reason. Since the oscillator and other functions are turned off during Power-down mode, any wake-up of the processor from Power-down mode makes use of the wake-up timer.

The wake-up timer monitors the crystal oscillator as the means of checking whether it is safe to begin code execution. When power is applied to the chip, or some event caused the chip to exit Power-down mode, some time is required for the oscillator to produce a signal of sufficient amplitude to drive the clock logic. The amount of time depends on many factors, including the rate of  $V_{DD}$  ramp (in the case of power on), the type of crystal and its electrical characteristics (if a quartz crystal is used), as well as any other external circuitry (e.g. capacitors), and the characteristics of the oscillator itself under the existing ambient conditions.

# 6.20.4 External interrupt inputs

The LPC2210/2220 include up to nine edge or level sensitive external interrupt inputs as selectable pin functions. When the pins are combined, external events can be processed as four independent interrupt signals. The external interrupt inputs can optionally be used to wake up the processor from Power-down mode.

# 6.20.5 Memory mapping control

The memory mapping control alters the mapping of the interrupt vectors that appear beginning at address 0x0000 0000. Vectors may be mapped to the bottom of the BANK0 external memory, or to the on-chip static RAM. This allows code running in different memory spaces to have control of the interrupts.

#### 6.20.6 Power control

The LPC2210/2220 support two reduced power modes: Idle mode and Power-down mode.

In Idle mode, execution of instructions is suspended until either a reset or interrupt occurs. Peripheral functions continue operation during Idle mode and may generate interrupts to cause the processor to resume execution. Idle mode eliminates power used by the processor itself, memory systems and related controllers, and internal buses.

In Power-down mode, the oscillator is shut down, and the chip receives no internal clocks. The processor state and registers, peripheral registers, and internal SRAM values are preserved throughout Power-down mode, and the logic levels of chip output pins remain static. The Power-down mode can be terminated and normal operation resumed by either a reset or certain specific interrupts that are able to function without clocks. Since all dynamic operation of the chip is suspended, Power-down mode reduces chip power consumption to nearly zero.

A power control for peripherals feature allows individual peripherals to be turned off if they are not needed in the application, resulting in additional power savings.

#### 6.20.7 APB

The APB divider determines the relationship between the processor clock (CCLK) and the clock used by peripheral devices (PCLK). The APB divider serves two purposes. The first is to provide peripherals with the desired PCLK via APB so that they can operate at the speed chosen for the ARM processor. In order to achieve this, the APB may be slowed down to  $\frac{1}{2}$  to  $\frac{1}{4}$  of the processor clock rate. Because the APB must work properly at power-up (and its timing cannot be altered if it does not work since the APB divider control registers reside on the APB), the default condition at reset is for the APB to run at  $\frac{1}{4}$  of the processor clock rate. The second purpose of the APB divider is to allow power savings when an application does not require any peripherals to run at the full processor rate. Because the APB divider is connected to the PLL output, the PLL remains active (if it was running) during Idle mode.

# 6.21 Emulation and debugging

The LPC2210/2220 support emulation and debugging via a JTAG serial port. A trace port allows tracing program execution. Debugging and trace functions are multiplexed only with GPIOs on Port 1. This means that all communication, timer and interface peripherals residing on Port 0 are available during the development and debugging phase as they are when the application is run in the embedded system itself.

#### 6.21.1 EmbeddedICE

Standard ARM EmbeddedICE logic provides on-chip debug support. The debugging of the target system requires a host computer running the debugger software and an EmbeddedICE protocol converter. EmbeddedICE protocol converter converts the remote debug protocol commands to the JTAG data needed to access the ARM core.

The ARM core has a Debug Communication Channel (DCC) function built-in. The debug communication channel allows a program running on the target to communicate with the host debugger or another separate host without stopping the program flow or even entering the debug state. The debug communication channel is accessed as a co-processor 14 by the program running on the ARM7TDMI-S core. The debug communication channel allows the JTAG port to be used for sending and receiving data without affecting the normal program flow. The debug communication channel data and control registers are mapped in to addresses in the EmbeddedICE logic.

The JTAG clock (TCK) must be slower than  $\frac{1}{6}$  of the CPU clock (CCLK) for the JTAG interface to operate.

#### 6.21.2 Embedded trace

Since the LPC2210/2220 have significant amounts of on-chip memory, it is not possible to determine how the processor core is operating simply by observing the external pins. The Embedded Trace Macrocell (ETM) provides real-time trace capability for deeply embedded processor cores. It outputs information about processor execution to the trace port.

The ETM is connected directly to the ARM core and not to the main AMBA system bus. It compresses the trace information and exports it through a narrow trace port. An external trace port analyzer must capture the trace information under software debugger control. Instruction trace (or PC trace) shows the flow of execution of the processor and provides a list of all the instructions that were executed. Instruction trace is significantly compressed by only broadcasting branch addresses as well as a set of status signals that indicate the pipeline status on a cycle by cycle basis. Trace information generation can be controlled by selecting the trigger resource. Trigger resources include address comparators, counters and sequencers. Since trace information is compressed the software debugger requires a static image of the code being executed. Self-modifying code cannot be traced because of this restriction.

#### 6.21.3 RealMonitor

RealMonitor is a configurable software module, developed by ARM Inc., which enables real-time debug. It is a lightweight debug monitor that runs in the background while users debug their foreground application. It communicates with the host using the debug communication channel, which is present in the EmbeddedICE logic. The LPC2210/2220 contain a specific configuration of RealMonitor software programmed into the on-chip flash memory.

# 7. Limiting values

Table 10. Limiting values reset

In accordance with the Absolute Maximum Rating System (IEC 60134).[1]

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DD(1V8)}$	supply voltage (1.8 V)		[2]	-0.5	+2.5	V
V <sub>DD(3V3)</sub>	supply voltage (3.3 V)		[3]	-0.5	+3.6	V
V <sub>DDA(3V3)</sub>	analog supply voltage (3.3 V)			-0.5	+4.6	V
V <sub>IA</sub>	analog input voltage			-0.5	+5.1	V
VI	input voltage	5 V tolerant I/O pins	[4][5]	-0.5	+6.0	V
		other I/O pins	[4][6]	-0.5	$V_{DD(3V3)} + 0.5$	V
I <sub>DD</sub>	supply current		[7][8]	-	100	mA
I <sub>SS</sub>	ground current		[8][9]	-	100	mA
T <sub>stg</sub>	storage temperature		[10]	-65	+150	°C
P <sub>tot(pack)</sub>	total power dissipation (per package)	based on package heat transfer, not device power consumption		-	1.5	W
V <sub>esd</sub>	electrostatic discharge voltage	human body model	[11]			
		all pins		-2000	+2000	V

- [1] The following applies to Table 10:
  - a) This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.
  - b) Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise noted.
- [2] Internal rail.
- [3] External rail.
- [4] Including voltage on outputs in 3-state mode.
- [5] Only valid when the  $V_{DD(3V3)}$  supply voltage is present.
- [6] Not to exceed 4.6 V.
- [7] Per supply pin.
- [8] The peak current is limited to 25 times the corresponding maximum current.
- [9] Per ground pin.
- [10] Dependent on package type.
- [11] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 k $\Omega$  series resistor.

# 8. Static characteristics

Table 11. Static characteristics

 $T_{amb}$  = -40 °C to +85 °C for commercial applications, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
V <sub>DD(1V8)</sub>	supply voltage (1.8 V)		[2]	1.65	1.8	1.95	V
V <sub>DD(3V3)</sub>	supply voltage (3.3 V)		[3]	3.0	3.3	3.6	V
V <sub>DDA(3V3)</sub>	analog supply voltage (3.3 V)			2.5	3.3	3.6	V
Standard	port pins, RESET, RTCK						
I <sub>IL</sub>	LOW-level input current	$V_I = 0 V$ ; no pull-up		-	-	3	μΑ
I <sub>IH</sub>	HIGH-level input current	$V_I = V_{DD(3V3)}$ ; no pull-down		-	-	3	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_O = 0 \text{ V}, V_O = V_{DD(3V3)};$ no pull-up/down		-	-	3	μΑ
I <sub>latch</sub>	I/O latch-up current	$-(0.5V_{DD(3V3)}) < V_{I} < (1.5V_{DD(3V3)}); T_{j} < 125 °C$		100	-	-	mA
$V_{I}$	input voltage		[4][5][6]	0	-	5.5	V
Vo	output voltage	output active		0	-	V <sub>DD(3V3)</sub>	V
V <sub>IH</sub>	HIGH-level input voltage			2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	0.8	V
V <sub>hys</sub>	hysteresis voltage			0.4	-	-	V
V <sub>OH</sub>	HIGH-level output voltage	$I_{OH} = -4 \text{ mA}$	[7]	V <sub>DD(3V3)</sub> – 0.4	-	-	V
$V_{OL}$	LOW-level output voltage	$I_{OL} = -4 \text{ mA}$	[7]	-	-	0.4	V
I <sub>OH</sub>	HIGH-level output current	$V_{OH} = V_{DD(3V3)} - 0.4 \text{ V}$	[7]	-4	-	-	mΑ
$I_{OL}$	LOW-level output current	$V_{OL} = 0.4 V$	[7]	4	-	-	mA
I <sub>OHS</sub>	HIGH-level short circuit output current	$V_{OH} = 0 V$	[8]	-	-	<b>–45</b>	mA
I <sub>OLS</sub>	LOW-level short circuit output current	$V_{OL} = V_{DD(3V3)}$	[8]	-	-	50	mA
$I_{pd}$	pull-down current	V <sub>I</sub> = 5 V	[9]	10	50	150	μΑ
I <sub>pu</sub>	pull-up current	$V_I = 0 V$	[10]	-15	-50	-85	μΑ
		$V_{DD(3V3)} < V_{I} < 5 V$	[9]	0	0	0	μΑ
I <sub>DD(act)</sub>	active mode supply current	$V_{DD(1V8)} = 1.8 \text{ V};$ $T_{amb} = 25 \text{ °C};$ code while(1){} executed from on-chip RAM; no active peripherals					
		CCLK = 60 MHz (LPC2210)		-	50	70	mA
		CCLK = 75 MHz (LPC2210/01; LPC2220)		-	50	70	mA

Table 11. Static characteristics ... continued

 $T_{amb}$  = -40 °C to +85 °C for commercial applications, unless otherwise specified.

arrib		• •	•				
Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
I <sub>DD(pd)</sub>	Power-down mode supply current	$V_{DD(1V8)} = 1.8 \text{ V};$ $T_{amb} = 25 ^{\circ}\text{C}$		-	10	-	μΑ
		$V_{DD(1V8)} = 1.8 \text{ V};$ $T_{amb} = 85 ^{\circ}\text{C}$		-	110	500	μΑ
I <sup>2</sup> C-bus p	ins						
V <sub>IH</sub>	HIGH-level input voltage			0.7V <sub>DD(3V3)</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	0.3V <sub>DD(3V3)</sub>	V
V <sub>hys</sub>	hysteresis voltage			-	0.5V <sub>DD(3V3)</sub>	-	V
V <sub>OL</sub>	LOW-level output voltage	$I_{OLS} = 3 \text{ mA}$	[7]	-	-	0.4	V
ILI	input leakage current	$V_I = V_{DD(3V3)}$	[11]	-	2	4	μΑ
		V <sub>I</sub> = 5 V		-	10	22	μΑ
Oscillato	r pins						
V <sub>i(XTAL1)</sub>	input voltage on pin XTAL1			0	-	1.8	V
V <sub>o(XTAL2)</sub>	output voltage on pin XTAL2			0	-	1.8	V

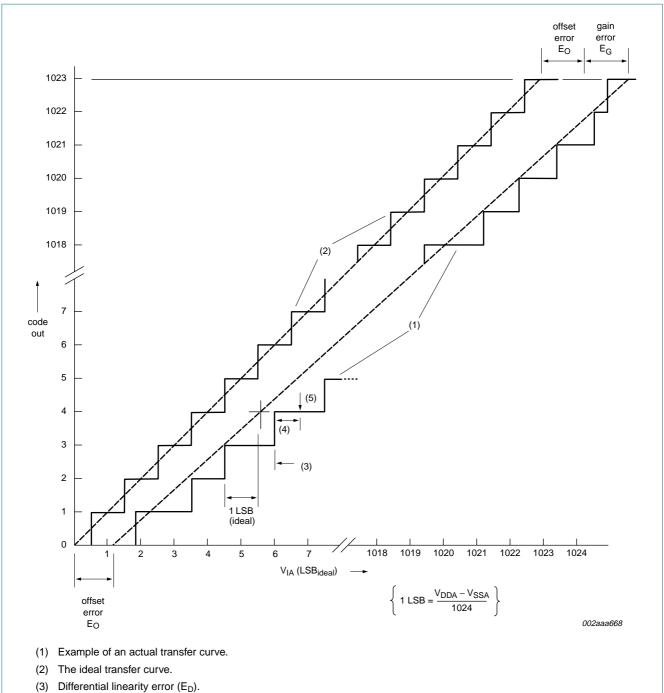
- [1] Typical ratings are not guaranteed. The values listed are at room temperature (+25 °C), nominal supply voltages.
- [2] Internal rail.
- [3] External rail.
- [4] Including voltage on outputs in 3-state mode.
- [5]  $V_{DD(3V3)}$  supply voltages must be present.
- [6] 3-state outputs go into 3-state mode when V<sub>DD(3V3)</sub> is grounded.
- [7] Accounts for 100 mV voltage drop in all supply lines.
- [8] Allowed as long as the current limit does not exceed the maximum current allowed by the device.
- [9] Minimum condition for  $V_1 = 4.5 \text{ V}$ , maximum condition for  $V_1 = 5.5 \text{ V}$ .
- [10] Applies to P1[25:16].
- [11] To  $V_{SS}$ .

Table 12. ADC static characteristics

 $V_{DDA(3V3)} = 2.5 \text{ V to } 3.6 \text{ V}$ ;  $T_{amb} = -40 \,^{\circ}\text{C}$  to  $+85 \,^{\circ}\text{C}$  unless otherwise specified. ADC frequency 4.5 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{IA}$	analog input voltage		0	-	$V_{DDA(3V3)}$	V
C <sub>ia</sub>	analog input capacitance		-	-	1	pF
E <sub>D</sub>	differential linearity error		[1][2][3]	-	±1	LSB
E <sub>L(adj)</sub>	integral non-linearity		[1][4]	-	±2	LSB
Eo	offset error		[1][5]	-	±3	LSB
E <sub>G</sub>	gain error		[1][6]	-	±0.5	%
E <sub>T</sub>	absolute error		[1][7]	-	±4	LSB

- [1] Conditions:  $V_{SSA} = 0 \text{ V}$ ,  $V_{DDA(3V3)} = 3.3 \text{ V}$ .
- [2] The ADC is monotonic, there are no missing codes.
- [3] The differential linearity error (E<sub>D</sub>) is the difference between the actual step width and the ideal step width. See Figure 5.
- [4] The integral non-linearity (E<sub>L(adj)</sub>) is the peak difference between the center of the steps of the actual and the ideal transfer curve after appropriate adjustment of gain and offset errors. See Figure 5.
- [5] The offset error (E<sub>O</sub>) is the absolute difference between the straight line which fits the actual curve and the straight line which fits the ideal curve. See Figure 5.
- [6] The gain error (E<sub>G</sub>) is the relative difference in percent between the straight line fitting the actual transfer curve after removing offset error, and the straight line which fits the ideal transfer curve. See Figure 5.
- [7] The absolute voltage error (E<sub>T</sub>) is the maximum difference between the center of the steps of the actual transfer curve of the non-calibrated ADC and the ideal transfer curve. See Figure 5.



- (4) Integral non-linearity  $(E_{L(adj)})$ .
- (5) Center of a step of the actual transfer curve.

Fig 5. **ADC** characteristics

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# 9. Dynamic characteristics

Table 13. Dynamic characteristics

 $T_{amb} = 0 \,^{\circ}\text{C}$  to  $+70 \,^{\circ}\text{C}$  for commercial applications,  $-40 \,^{\circ}\text{C}$  to  $+85 \,^{\circ}\text{C}$  for industrial applications,  $V_{DD(3V3)}$  over specified ranges. [1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
External clos	ck					
f <sub>osc</sub>	oscillator frequency	supplied by an external oscillator (signal generator)	1	-	25	MHz
		external clock frequency supplied by an external crystal oscillator	1	-	25	MHz
		external clock frequency if on-chip PLL is used	10	-	25	MHz
		external clock frequency if on-chip bootloader is used for initial code download	10	-	25	MHz
T <sub>cy(clk)</sub>	clock cycle time		20	-	1000	ns
t <sub>CHCX</sub>	clock HIGH time		$T_{cy(clk)} \times 0.4$	-	-	ns
t <sub>CLCX</sub>	clock LOW time		$T_{cy(clk)} \times 0.4$	-	-	ns
t <sub>CLCH</sub>	clock rise time		-	-	5	ns
t <sub>CHCL</sub>	clock fall time		-	-	5	ns
Port pins (ex	cept P0.2 and P0.3)					
t <sub>r</sub>	rise time		-	10	-	ns
t <sub>f</sub>	fall time		-	10	-	ns
I <sup>2</sup> C-bus pins	(P0.2 and P0.3)					
t <sub>f</sub>	fall time	V <sub>IH</sub> to V <sub>IL</sub>	[2] 20 + 0.1 × C <sub>b</sub>	, -	-	ns

<sup>[1]</sup> Parameters are valid over operating temperature range unless otherwise specified.

<sup>[2]</sup> Bus capacitance C<sub>b</sub> in pF, from 10 pF to 400 pF.

Table 14. External memory interface dynamic characteristics

 $C_L = 25 \; pF; \; T_{amb} = 40 \; ^{\circ}C.$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Common	to read and write cycles					
t <sub>CHAV</sub>	XCLK HIGH to address valid time		-	-	10	ns
t <sub>CHCSL</sub>	XCLK HIGH to $\overline{\text{CS}}$ LOW time		-	-	10	ns
tснсsн	XCLK HIGH to $\overline{\text{CS}}$ HIGH time		-	-	10	ns
t <sub>CHANV</sub>	XCLK HIGH to address invalid time		-	-	10	ns
Read cyc	le parameters					
t <sub>CSLAV</sub>	CS LOW to address valid time	<u>[1]</u>	-5	-	+10	ns
t <sub>OELAV</sub>	OE LOW to address valid time	[1]	-5	-	+10	ns
t <sub>CSLOEL</sub>	$\overline{\text{CS}}$ LOW to $\overline{\text{OE}}$ LOW time		-5	-	+5	ns
t <sub>am</sub>	memory access time	[2][3] [4]	$(T_{\text{cy(CCLK)}} \times (2 + \text{WST1})) + (-20)$	-	-	ns
t <sub>am(ibr)</sub>	memory access time (initial burst-ROM)	[2][3] [4]	$(T_{cy(CCLK)} \times (2 + WST1)) + (-20)$	-	-	ns
t <sub>am(sbr)</sub>	memory access time (subsequent burst-ROM)	[2][5]	$T_{\rm cy(CCLK)} + (-20)$	-	-	ns
t <sub>h(D)</sub>	data hold time	[6]	0	-	-	ns
t <sub>CSHOEH</sub>	CS HIGH to OE HIGH time		<b>-</b> 5	-	+5	ns
t <sub>OEHANV</sub>	OE HIGH to address invalid time		-5	-	+5	ns
t <sub>CHOEL</sub>	XCLK HIGH to $\overline{\text{OE}}$ LOW time		<b>-</b> 5	-	+5	ns
tсноен	XCLK HIGH to $\overline{\text{OE}}$ HIGH time		-5	-	+5	ns
Write cyc	le parameters					
t <sub>AVCSL</sub>	address valid to $\overline{\text{CS}}$ LOW time	<u>[1]</u>	$T_{cy(CCLK)} - 10$	-	-	ns
t <sub>CSLDV</sub>	CS LOW to data valid time		-5	-	+5	ns
t <sub>CSLWEL</sub>	CS LOW to WE LOW time		-5	-	+5	ns
tcslblsl	CS LOW to BLS LOW time		-5	-	+5	ns
t <sub>WELDV</sub>	WE LOW to data valid time		-5	-	+5	ns
t <sub>CSLDV</sub>	CS LOW to data valid time		-5	-	+5	ns
t <sub>WELWEH</sub>	WE LOW to WE HIGH time	[2][4]	$T_{cy(CCLK)} \times (1 + WST2) - 5$	-	$T_{cy(CCLK)} \times (1 + WST2) + 5$	ns
t <sub>BLSLBLSH</sub>	BLS LOW to BLS HIGH time	[2][4]	$T_{\text{cy(CCLK)}} \times (1 + \text{WST2}) - 5$	-	$T_{cy(CCLK)} \times (1 + WST2) + 5$	ns
t <sub>WEHANV</sub>	WE HIGH to address invalid time	[2]	T <sub>cy(CCLK)</sub> – 5	-	$T_{cy(CCLK)} + 5$	ns
t <sub>WEHDNV</sub>	WE HIGH to data invalid time	[2]	$(2 \times T_{cy(CCLK)}) - 5$	-	$(2 \times T_{cy(CCLK)}) + 5$	ns
t <sub>BLSHANV</sub>	BLS HIGH to address invalid time	[2]	T <sub>cy(CCLK)</sub> – 5	-	$T_{cy(CCLK)} + 5$	ns

**Table 14.** External memory interface dynamic characteristics ...continued  $C_L = 25 \ pF$ ;  $T_{amb} = 40 \ ^{\circ}C$ .

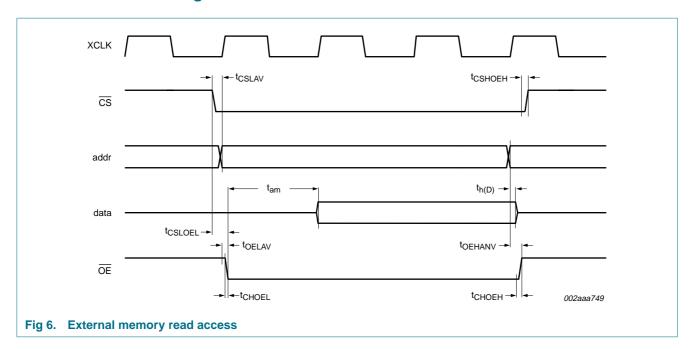
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>BLSHDNV</sub>	BLS HIGH to data invalid time	<u>[2</u>	$(2 \times T_{\text{cy(CCLK)}}) - 5$	-	$(2 \times T_{cy(CCLK)}) + 5$	ns
t <sub>CHDV</sub>	XCLK HIGH to data valid time		-	-	10	ns
t <sub>CHWEL</sub>	XCLK HIGH to WE LOW time		-	-	10	ns
t <sub>CHBLSL</sub>	XCLK HIGH to $\overline{\text{BLS}}$ LOW time		-	-	10	ns
t <sub>CHWEH</sub>	XCLK HIGH to $\overline{\text{WE}}$ HIGH time		-	-	10	ns
t <sub>CHBLSH</sub>	XCLK HIGH to $\overline{\text{BLS}}$ HIGH time		-	-	10	ns
t <sub>CHDNV</sub>	XCLK HIGH to data invalid time		-	-	10	ns

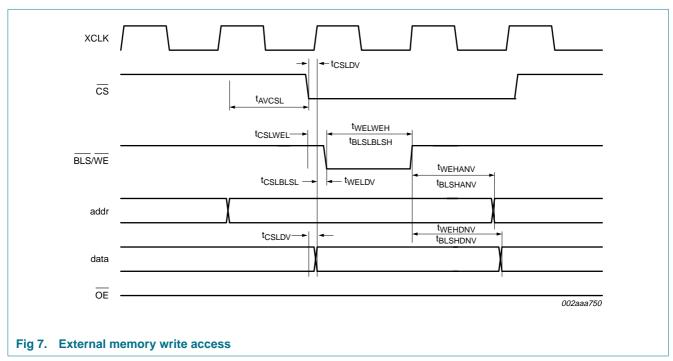
- [1] Except on initial access, in which case the address is set up  $T_{\text{cy(CCLK)}}$  earlier.
- [2]  $T_{cy(CCLK)} = \frac{1}{CCLK}$ .
- [3] Latest of address valid,  $\overline{\text{CS}}$  LOW,  $\overline{\text{OE}}$  LOW to data valid.
- [4] See the LPC2210/20 user manual UM10114\_1 for a description of the WSTn bits.
- [5] Address valid to data valid.
- [6] Earliest of  $\overline{\text{CS}}$  HIGH,  $\overline{\text{OE}}$  HIGH, address change to data invalid.

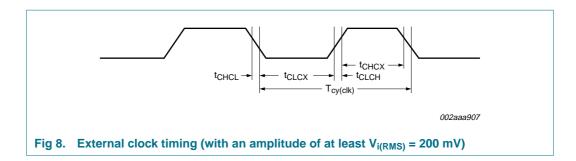
Table 15. Standard read access specifications

Access cycle	Max frequency	WST setting WST ≥ 0; round up to integer	Memory access time requirement
standard read	$f_{MAX} \le \frac{2 + WSTI}{t_{RAM} + 20 \ ns}$	$WSTI \ge \frac{t_{RAM} + 20 \ ns}{t_{cy(CCLK)}} - 2$	$t_{RAM} \le t_{cy(CCLK)} \times (2 + WST1) - 20 \text{ ns}$
standard write	$f_{MAX} \le \frac{1 + WST2}{t_{WRITE} + 5 \ ns}$	$WST2 \ge \frac{t_{WRITE} - t_{CYC} + 5}{t_{cy(CCLK)}}$	$t_{WRITE} \le t_{cy(CCLK)} \times (1 + WST2) - 5 \text{ ns}$
burst read - initial	$f_{MAX} \le \frac{2 + WSTI}{t_{INIT} + 20 \ ns}$	$WSTI \ge \frac{t_{INIT} + 20 \ ns}{t_{cy(CCLK)}} - 2$	$t_{INIT} \le t_{cy(CCLK)} \times (2 + WST1) - 20 \text{ ns}$
burst read - subsequent 3×	$f_{MAX} \le \frac{1}{t_{ROM} + 20 \ ns}$	N/A	$t_{ROM} \le t_{cy(CCLK)} - 20 \ ns$

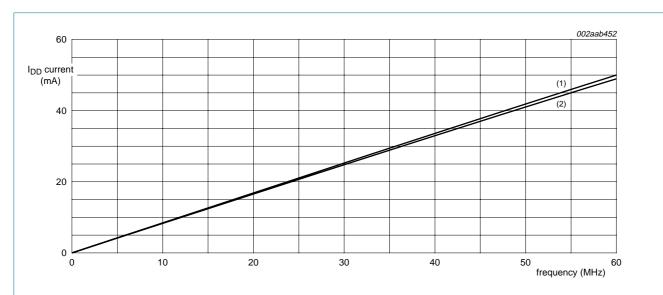
# 9.1 Timing







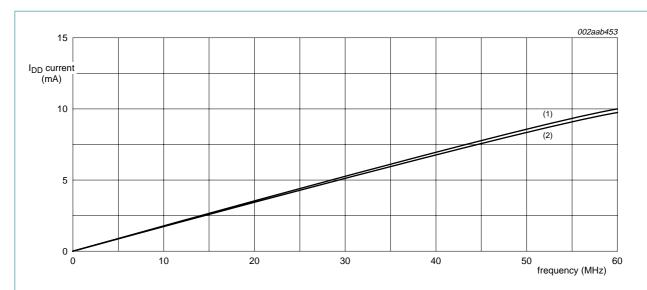
### 9.2 LPC2210 power consumption measurements



Test conditions: code executed from on-chip RAM; all peripherals are enabled in PCONP register; PCLK = CCLK/4.

- (1) 1.8 V core at 25 °C (typical)
- (2) 1.65 V core at 25 °C (typical)

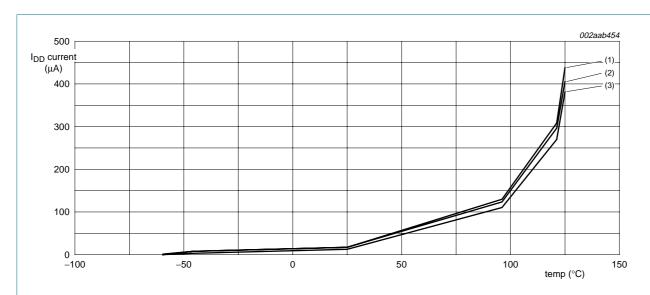
Fig 9. LPC2210 I<sub>DD</sub> in Active mode measured at different frequencies (CCLK) and temperatures



Test conditions: Idle mode entered executing code from on-chip RAM; all peripherals are enabled in PCONP register; PCLK = CCLK/4.

- (1) 1.8 V core at 25 °C (typical)
- (2) 1.65 V core at 25 °C (typical)

Fig 10. LPC2210 I<sub>DD</sub> in Idle mode measured at different frequencies (CCLK) and temperatures

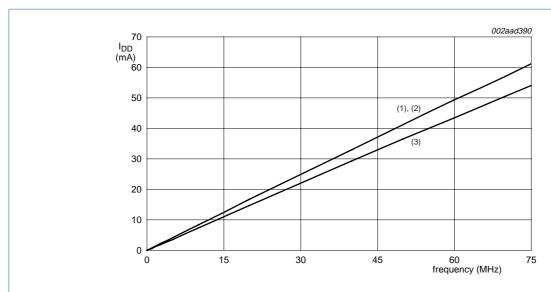


Test conditions: Power-down mode entered executing code from on-chip RAM; all peripherals are enabled in PCONP register.

- (1) 1.95 V core
- (2) 1.8 V core
- (3) 1.65 V core

Fig 11. LPC2210  $I_{DD}$  in Power-down mode measured at different temperatures

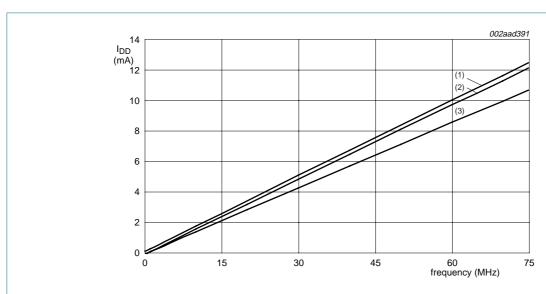
### 9.3 LPC2220 and LPC2210/01 power consumption measurements



Test conditions: code executed from on-chip RAM; all peripherals are enabled in PCONP register; PCLK = CCLK/4.

- (1) 1.8 V core at 85 °C (typical)
- (2) 1.8 V core at 25 °C (typical)
- (3) 1.65 V core at 25 °C (typical)

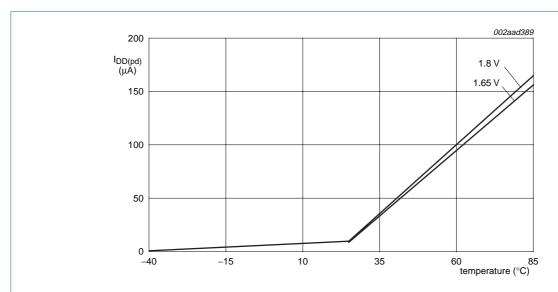
Fig 12. LPC2220 and LPC2210/01 I<sub>DD</sub> in Active mode measured at different frequencies (CCLK) and temperatures



Test conditions: Idle mode entered executing code from on-chip RAM; all peripherals are enabled in PCONP register; PCLK = CCLK/4.

- (1) 1.8 V core at 85 °C (typical)
- (2) 1.8 V core at 25 °C (typical)
- (3) 1.65 V core at 25 °C (typical)

Fig 13. LPC2220 and LPC2210/01  $I_{DD}$  in Idle mode measured at different frequencies (CCLK) and temperatures



Test conditions: Power-down mode entered executing code from on-chip RAM; all peripherals are enabled in PCONP register.

Fig 14. LPC2220 and LPC2210/01 I<sub>DD</sub> in Power-down mode measured at different temperatures

# 10. Package outline

LQFP144: plastic low profile quad flat package; 144 leads; body 20 x 20 x 1.4 mm

SOT486-1

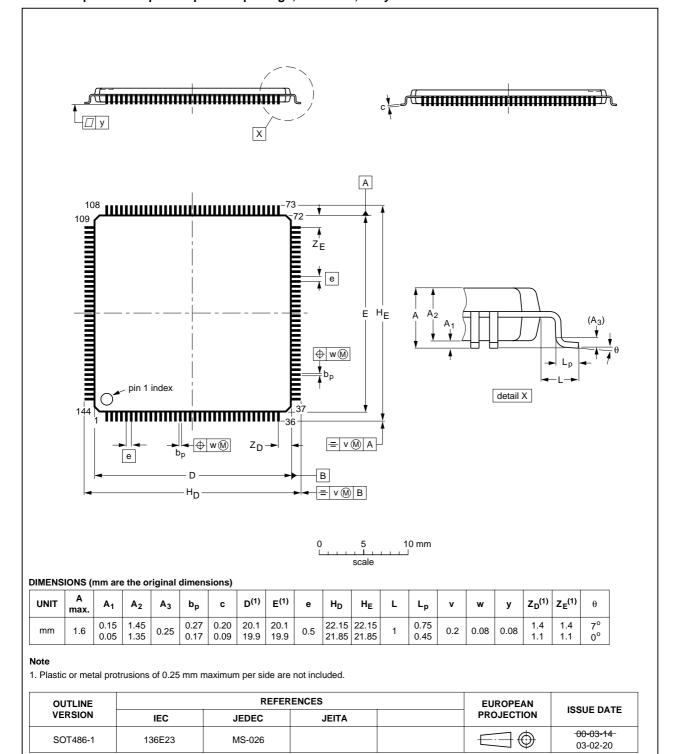


Fig 15. Package outline SOT486-1 (LQFP144)

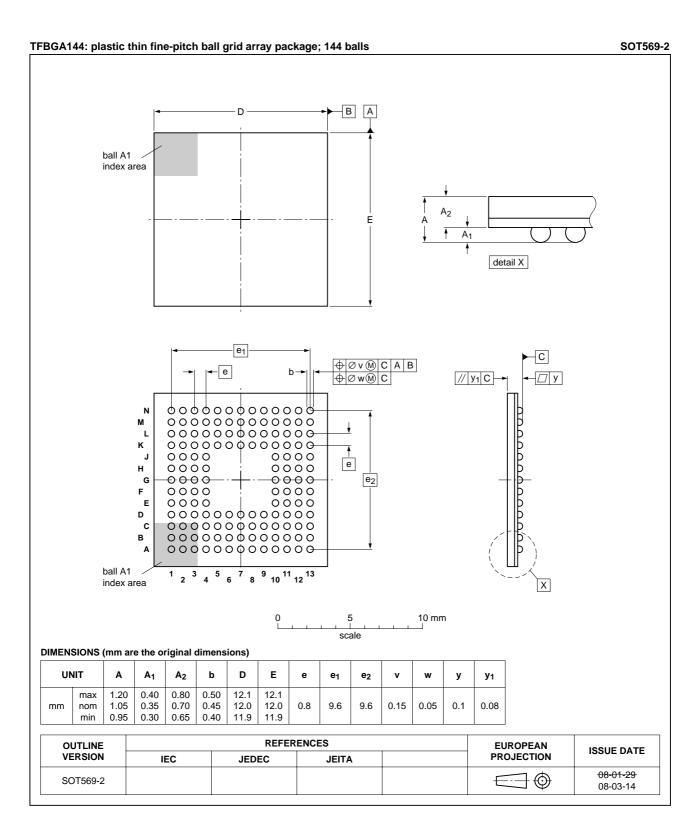


Fig 16. Package outline SOT569-2 (TFBGA144)

# 11. Abbreviations

Table 16. Acronym list

Acronym	Description
ADC	Analog-to-Digital Converter
AMBA	Advanced Microcontroller Bus Architecture
APB	Advanced Peripheral Bus
CISC	Complex Instruction Set Computer
FIFO	First In, First Out
GPIO	General Purpose Input/Output
I/O	Input/Output
JTAG	Joint Test Action Group
PWM	Pulse Width Modulator
RISC	Reduced Instruction Set Computer
SPI	Serial Peripheral Interface
SSI	Serial Synchronous Interface
SRAM	Static Random Access Memory
TTL	Transistor-Transistor Logic
UART	Universal Asynchronous Receiver/Transmitter

# 12. Revision history

Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
LPC2210_2220_6	20081211	Product data sheet	-	LPC2210_2220_5
Modifications:	figure note  Table 11 "S  Table 11 "S  Maximum fi  Changed S	kternal clock timing (with arrow "V <sub>DD</sub> = 1.8 V", updated tatic characteristics": V <sub>hys</sub> , tatic characteristics": modificequency f <sub>osc</sub> for external of OT569-1 to SOT569-2.	graphic and figure title. moved 0.4 from Typ to N ied Table note 8. scillator and external cry	rstal updated.
LPC2210_2220_5	20071220	Product data sheet	-	LPC2210_2220_4
Modifications:	<ul> <li>LPC2210FE</li> </ul>	3D144/01 added.		
	<ul> <li>New power</li> </ul>	consumption measuremen	ts for LPC2220 and LPC	C2210/01 included.
LPC2210_2220_4	20071002	Product data sheet	-	LPC2210_2220_3
LPC2210_2220_3	20070213	Product data sheet	-	LPC2210_2220_2
LPC2210_2220_2	20050530	Product data sheet	-	LPC2210-01
LPC2210-01	20040209	Preliminary data	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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